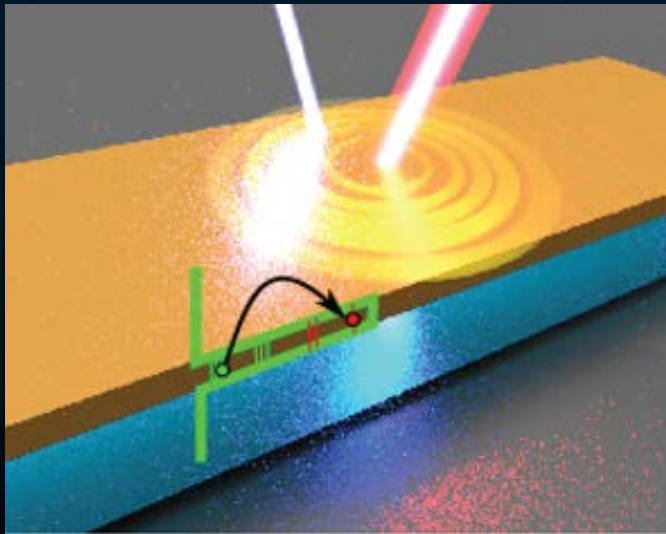


Emerging Materials for Nanophotonics and Plasmonics: Roads Ahead



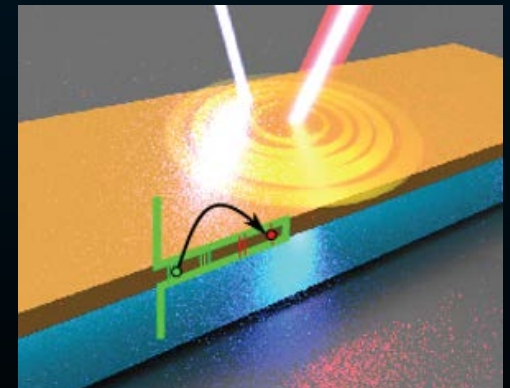
*BUILDING NANOSCALE PHOTONIC
TECHNOLOGIES OF THE FUTURE*

Alexandra Boltasseva

School of Electrical & Computer Engineering
Birck Nanotechnology Center
PURDUE UNIVERSITY

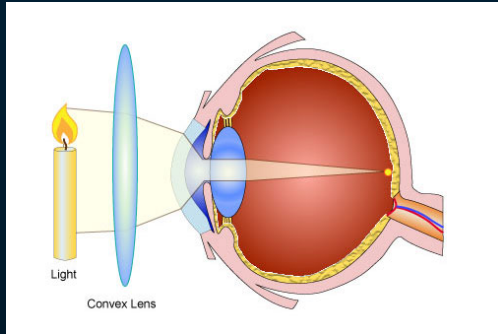
OUTLINE

- Plasmonics: Loss and Gain
- Expanding Materials Playground for Plasmonics and Nanophotonics
- Metal Nitrides
- Transparent Conducting Oxides
- Material Requirements: Tunability & T-Stability
- Ultra-Thin Plasmonic Metal Nitrides
- MXenes: Novel Quasi-2D Materials
- Outlook



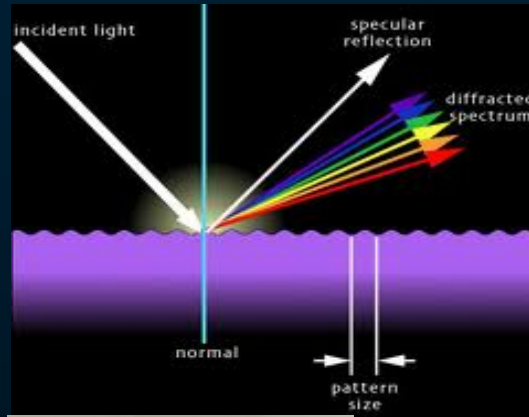
BASIC LAWS OF OPTICS

Refraction



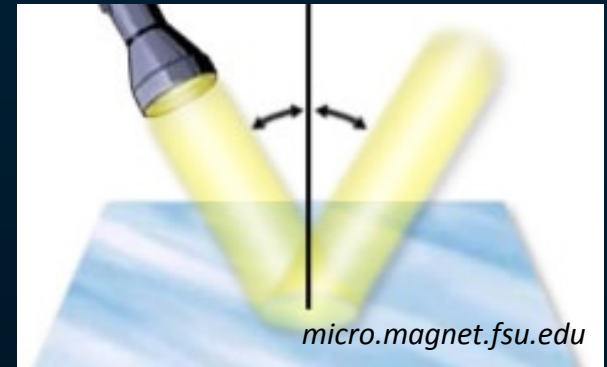
www.passmyexams.co.uk

Diffraction



Wikipedia

Reflection



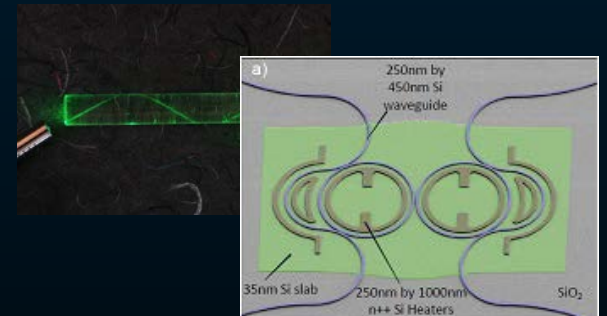
asvus.it



<http://eco-globe.com>



Wikipedia



Lipson group

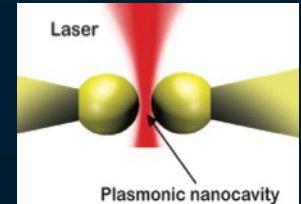
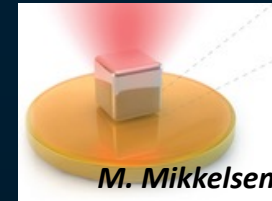
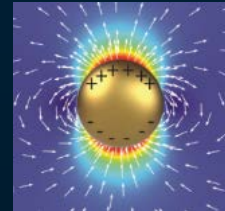
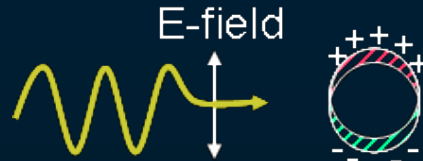


Wikipedia

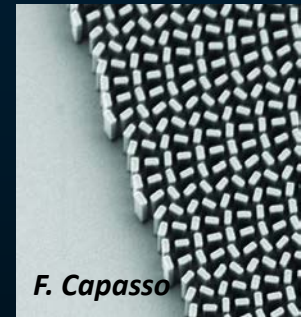
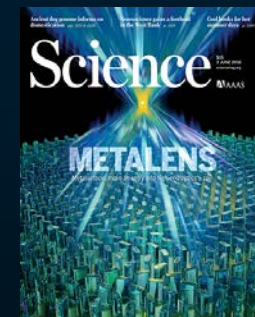
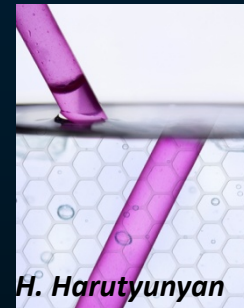
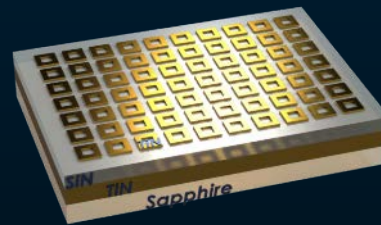
PLASMONICS/NANOPHOTONICS

- **Localized Surface Plasmons** = Optical Nano-Antenna (imaging, sensing, therapy, energy...)

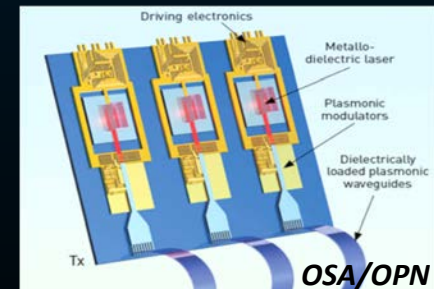
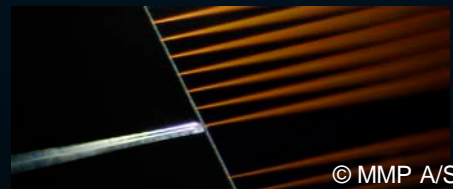
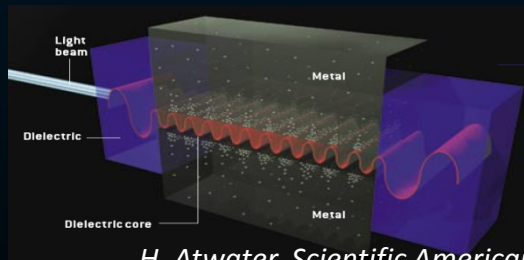
Free – electrons
Negative epsilon



= Optical Metasurfaces/Metamaterials



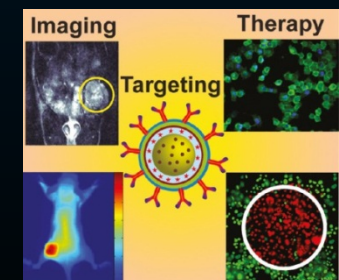
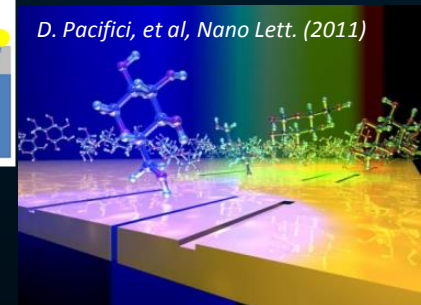
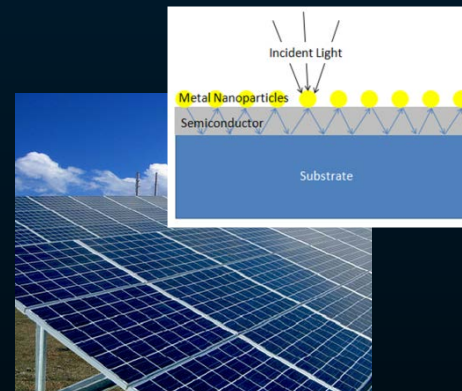
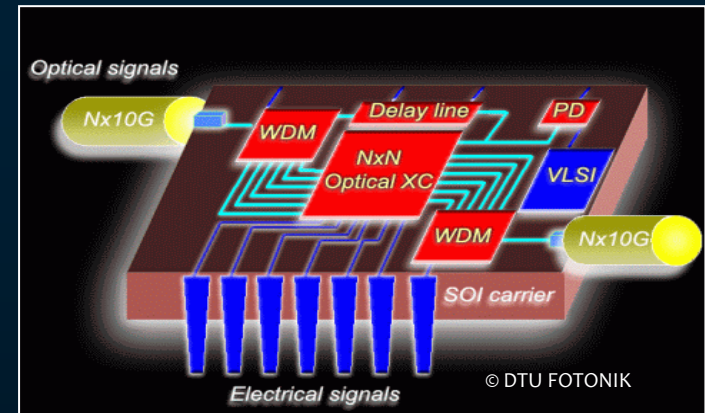
- **Propagating SP** = Nano-Waveguide (on-chip photonics/optoelectronics, lab-on-a-chip...)



- **Epsilon-Near-Zero** = Enhanced nonlinearities, ultra-fast switching, tunnelling, etc

POTENTIAL TECHNOLOGY IMPACT

- On-chip optics/Hybrid photon./electronic circuits
- Sub- λ photodetectors
- Data recording/storage
- Single molecule sensors
- Medical/Drug delivery/Therapy
- Sub- λ imaging
- Optical nanolithography
- Optical nanotweezers
- Solar cells/PV
- Photo-catalysis
- Novel energy conversion schemes
- Quantum information technology

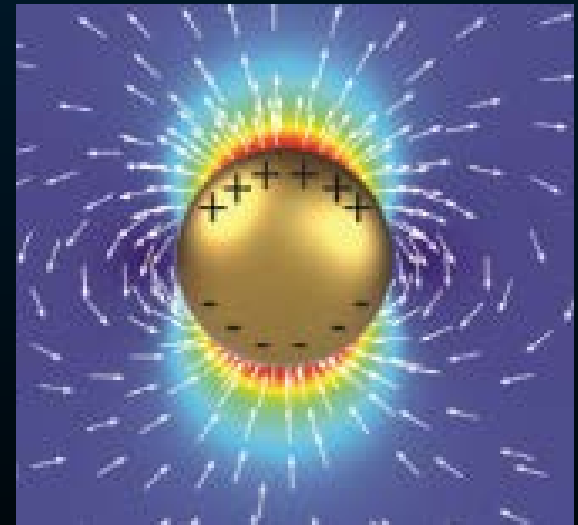
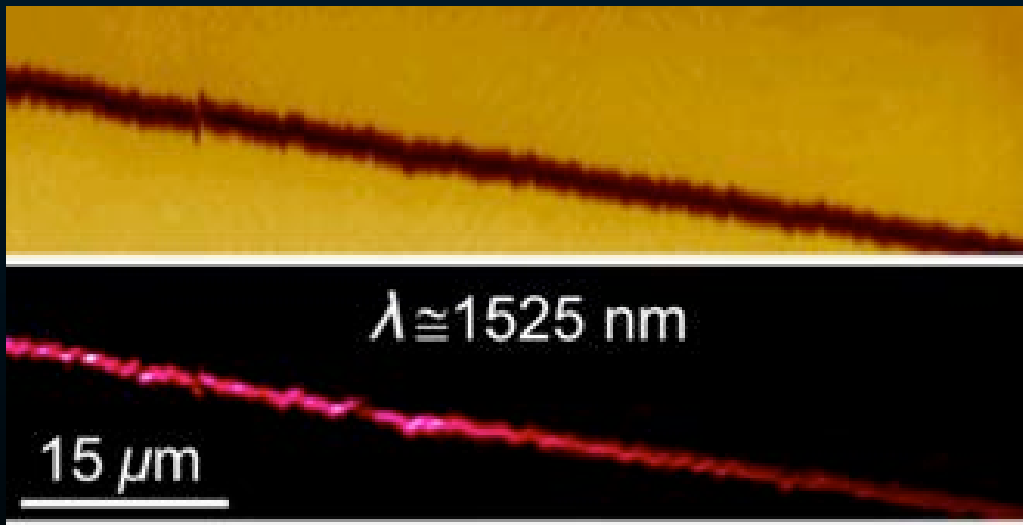
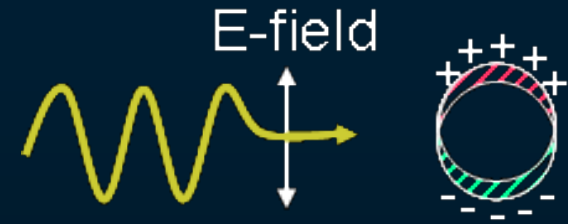


PLASMONICS & LOSS

Plasmonic building blocks

NOBLE METALS:

- Much light is absorbed!
(Ohmic loss)



LOSS CAN BE USEFUL!

APPLIED PHYSICS

Plasmonics—turning loss into gain

The optical losses usually associated with plasmonic materials could be used in applications

By Justus C. Ndukaife,^{1,2} Vladimir M. Shalaev,¹ Alexandra Boltasseva¹

The light-induced electronic excitations that occur at the surface of metals—plasmons—provide the extraordinary ability to confine electromagnetic energy to the subwavelength scale. Such extreme optical confinement can

enhance the light-matter interaction and enable miniaturized optical and optoelectronic devices. However, this confinement requires that plasmonic materials possess free carriers, which unavoidably results in light being lost or absorbed in the system (1). This optical loss has hampered the realization of device designs with ultracompact, on-chip optical components and nanome-

ter-scale resolution imaging. Because of the detrimental effects of plasmonic losses, several avenues are being explored to mitigate the high absorption, such as using gain to compensate for the losses, and synthesizing alternative low-loss plasmonic materials (2). Rather than continuing to pursue low-loss plasmonics approaches, we draw attention to the benefit of losses by high-

334 22 JANUARY 2016 • VOL 351 ISSUE 6271

sciencemag.org **SCIENCE**

Published by AAAS

ILLUSTRATION: V. ALTOUNIAN/SCIENCE

W. Li, J. Valentine "Harvesting the Loss: Surface Plasmon-Based Hot Electron Photodetection", *Nanophoton.* 7, 177, 2017
Ndukaife, Shalaev & Boltasseva. "Plasmonics: Turning Loss into Gain", *Science* 351, 6271 (2016)

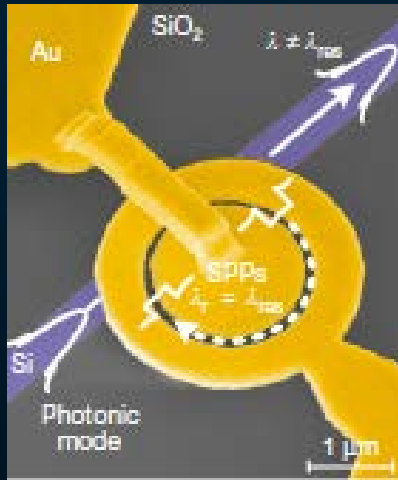
See J. Khurgin regarding plasmonic losses

J. B. Khurgin and G. Sun, "In search of elusive lossless metal", *APL* 96, 181102 (2010)

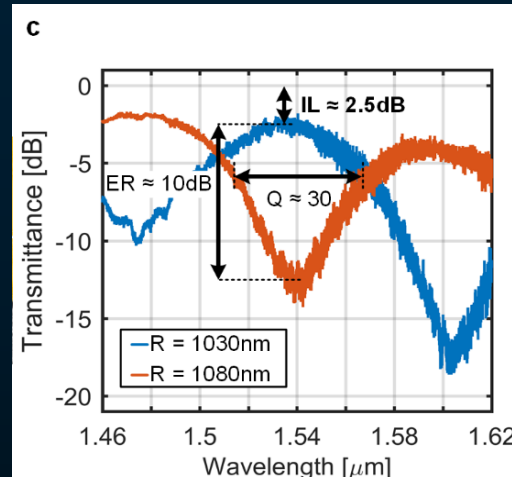
J. B. Khurgin and A. Boltasseva, *MRS Bulletin* (2012)

PLASMONICS FOR HYBRID ON-CHIP CIRCUITRY

Low-loss plasmon-assisted electro-optic modulator



SEM image of a plasmonic ring resonator and the corresponding transmittance



Operation

On State (non-resonant)

- Light passes through the WG

Off State (resonant)

- OEO changes refractive index under applied voltage
- Light couples into resonator

Si waveguide mode couple SURFACE PLASMON when **LOSS is ON!**

COMPACT (footprint of a few square micrometres)

HIGH SPEED (> 100 GHz) and **LOW LOSS** (< 3 dB)

C. Haffner, et al., *Nature* (April 26, 2018)

In collaboration with ETH, J. Leuthold, VCU, N. Kinsey, & U Wash

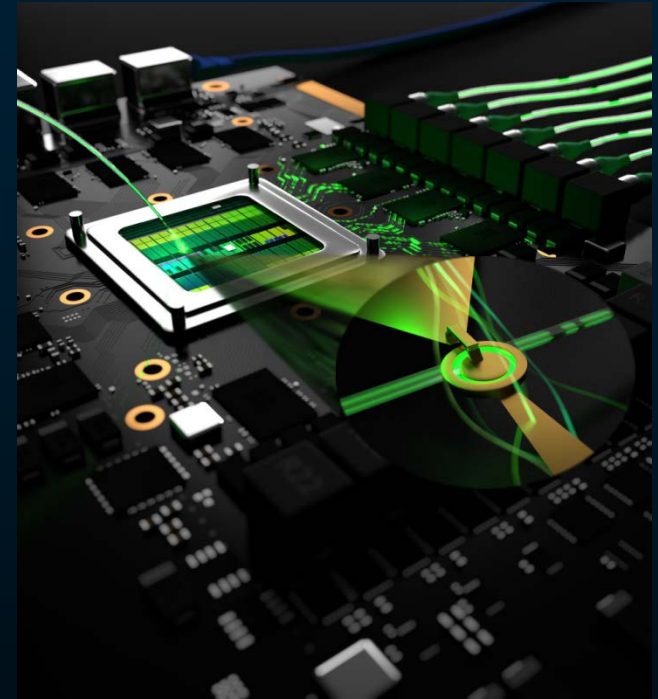
Plasmonic circuitry:

Berini, Bozhevolnyi, Zhang, Brongersma, Atwater, Zayats and other

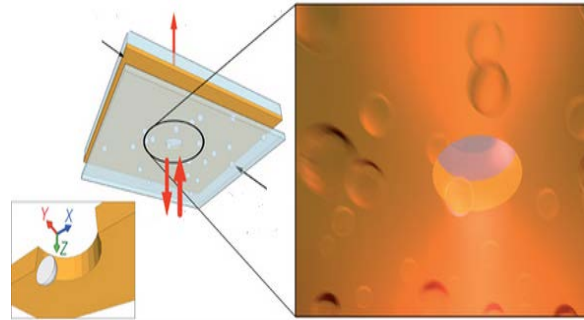
PLASMONICS FOR HYBRID ON-CHIP CIRCUITRY

Low-loss plasmon-assisted electro-optic modulator

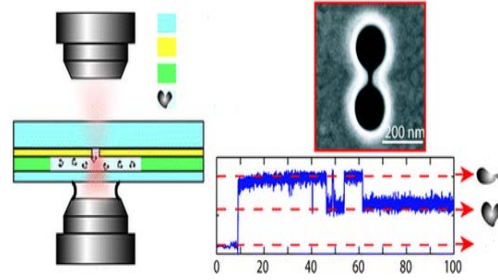
- **Compact** footprint (6 μm diameter) smaller than conventional SOI modulators and plasmonic MZIs
- **72Gbps** speed demonstrated experimentally
- Low Q (~ 30) – **higher thermal stability**
- Low energy consumption (12 fJ bit $^{-1}$ at 72 Gbit s $^{-1}$)
- **High bandwidth** (~ 100 GHz)



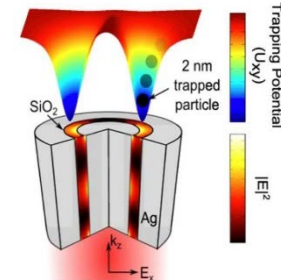
PLASMONIC NANOTWEEZERS



Juan et al. *Nature Physics* (2009)



Yuanjie et al. *Nano letters* (2011)

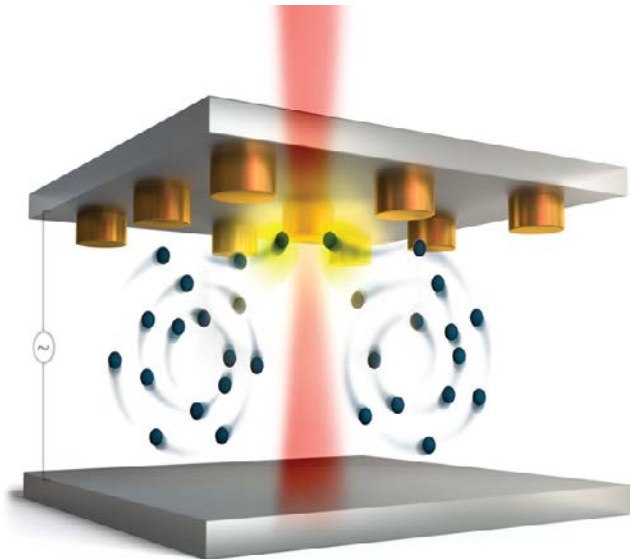


Amr et al. *Nano letters* (2012)

See also works from the groups of:

R. Quidant,
K. Crozier, L. Hesselink,
K. Toussaint, X. Zhang,
Y. Tsuboi, J. Dionne and
other

The Hybrid Electrothermoplasmonic Nanotweezer (HENT)



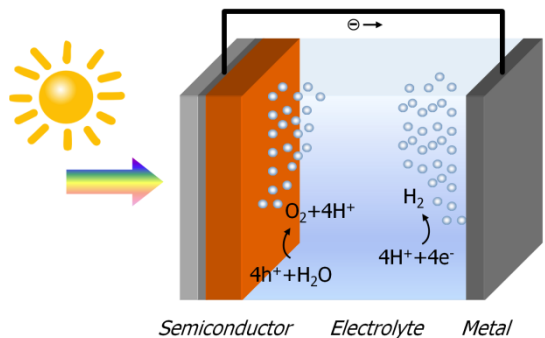
HENT Features:

- Laser + AC electric field:
on-demand fluid flow
- Fast and precise delivery to plasmonic hotspots
- High resolution nanoparticle trapping
- Ability to immobilize trapped object

R. Quidant: ETP- enhanced LSPR chip

With S. Wereley, Purdue
Ndukaife et al., *Nature Nanotechnology* (2016)
Ndukaife, Shalaev & Boltasseva. *Science* 351, 6271 (2016)

FROM SOLAR STEAM TO WATER SPLITTING

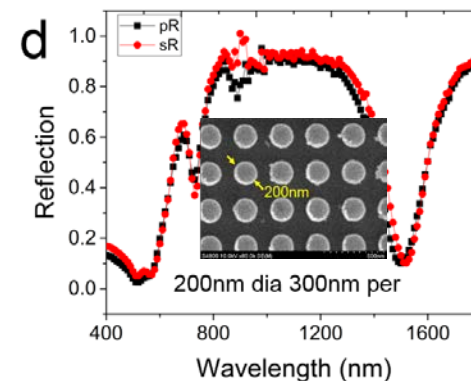
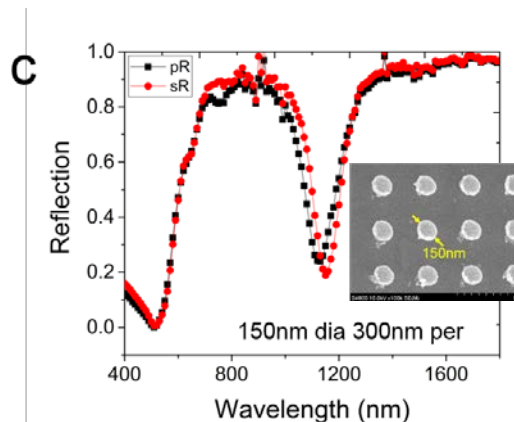
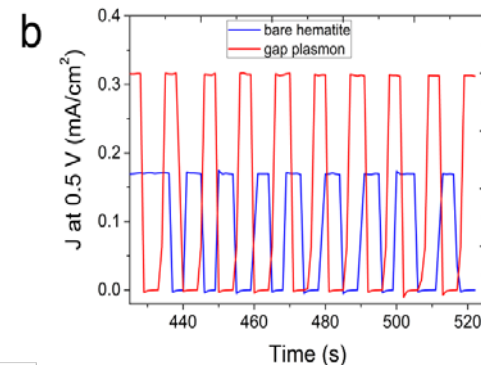
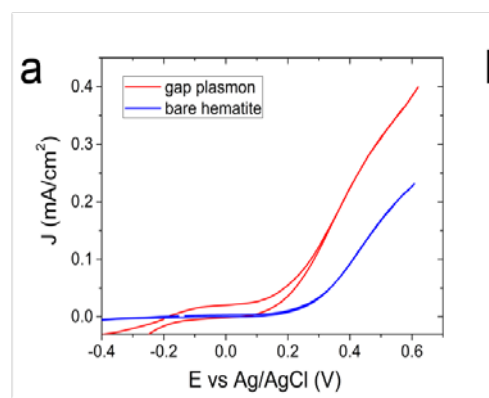
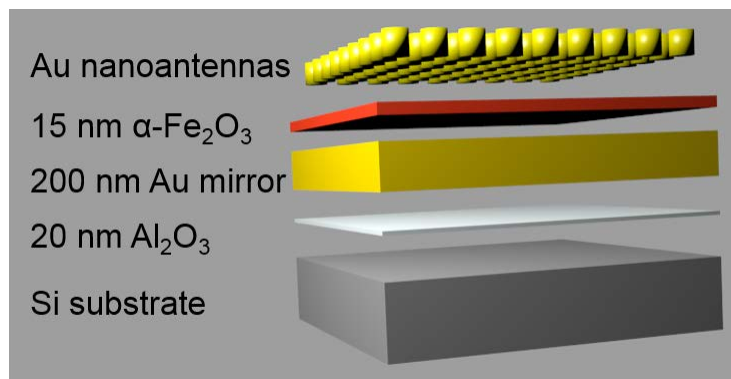


Water splitting with hematite

Collaboration with



- Plasmon enhanced solar water splitting
- Hematite bandgap 2.0-2.2eV (solar spectrum)
- Earth abundant/Commercially viable
- Photochemically stable
- Grown with Pulsed Laser Deposition



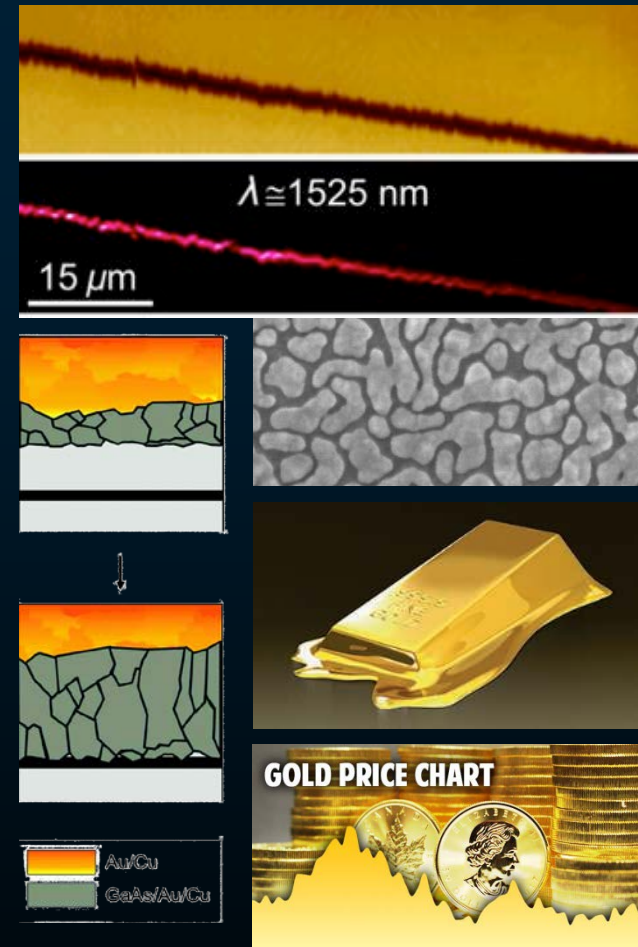
Photocurrent enhancement with gap plasmons
(See work by S. Bozhevolnyi)

MATERIALS BUILDING BLOCKS

Plasmonic NOBLE METALS:

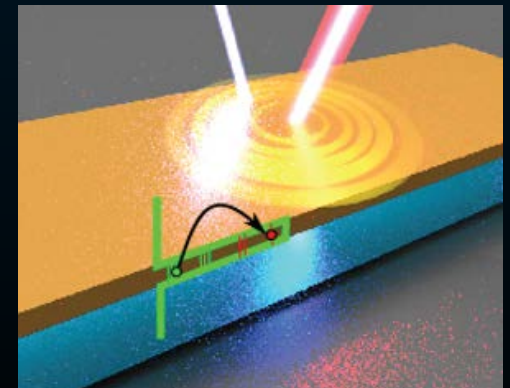
- Much light is absorbed (Ohmic LOSS)
- Not adjustable optical properties
- Hard to switch/tune
- Challenging fabrication
- Challenging integration
- Not CMOS-compatible
- Soft
- Low melting point
- High cost

***TUNABLE/SWITCHABLE response
and STABILITY remain a challenge!***



OUTLINE

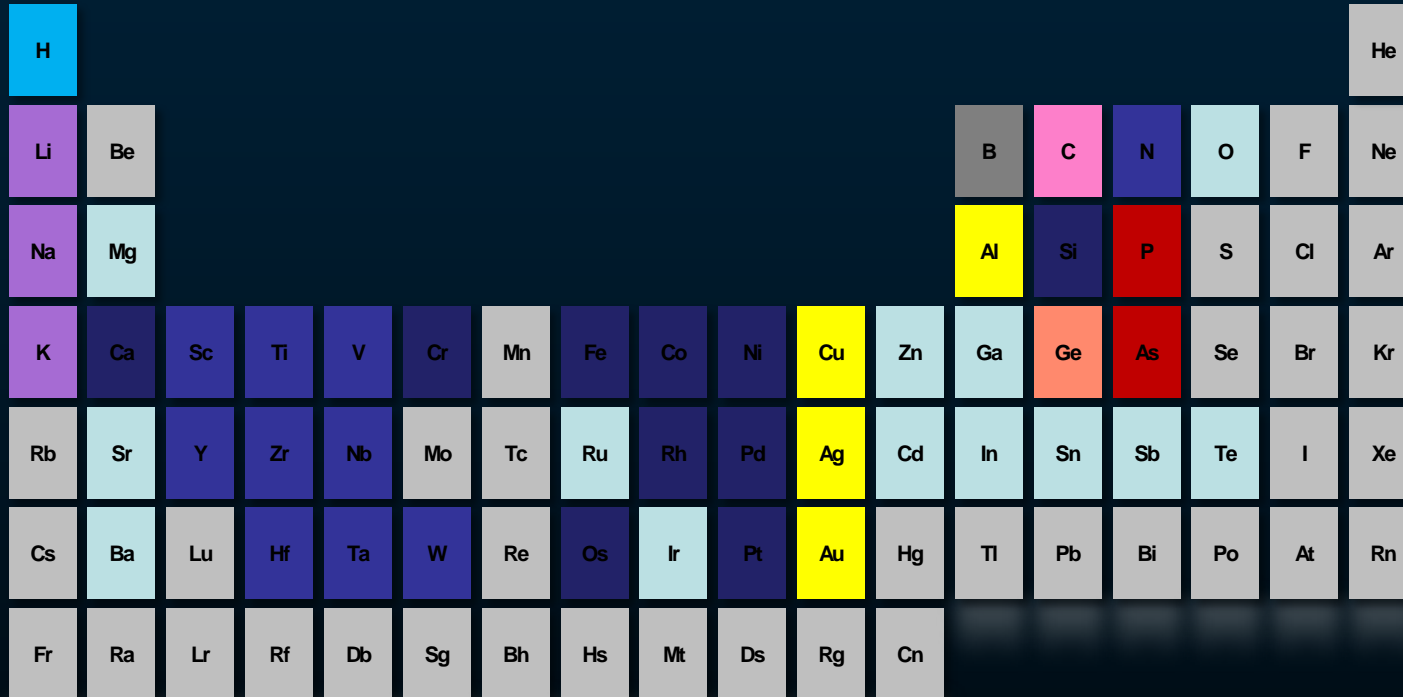
- Plasmonics: Loss and Gain
- Expanding Materials Playground for Plasmonics and Nanophotonics
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- Transparent Conducting Oxides
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- Ultra-Thin Plasmonic Metal Nitrides
- MXenes: Novel Quasi-2D Materials
- Outlook



PLASMONIC MATERIALS RESEARCH

Looking for intermediate carrier density materials

TUNABLE & ROBUST/STABLE & Sustainable



- TiN, TiAlN, Zr_xN_y, HfN, ScN, TaN, YN, VN, NbN, Cu₃N, WN
- SnO₂, In:SnO₂, ZnO, Ga:ZnO, Al:ZnO, InGa:ZnO, CdO, CdSb₂O₆, In₂O₃, GaInO₆, MgIn₂O₄, TiO₂, SrTiO₃, SrSnO₃, Cd₃TeO₆, BaSnO₃, SrGeO₃, IrO₂, VO₂, RuO₂
- CoSi₂, CrSi₂, FeSi₂, HfSi₂, IrSi₂, NbSi₂, Ni_xSi_x, Os₂Si₃, Pt₂Si, Pd₂Si, ReSi₂, RhSi₂, Ru₂Si₃, TaSi₂, TiSi₂, V_xSi_y, WSi₂, ZrSi₂, Ca₂Si, Mg₂Si
- Ru₂Ge₃, Os₂Ge₃, BaGe₃, SrGe₂, Ca₂Ge, Mg₂Ge, CrGe₂
- GaAs, AlGaAs, InGaAs, InP, AlInAs

■ Graphene ■ YH₂

■ Li, Na, K ■ MgB₂

■ Al, Cu, Ag, Au

See work by E. Hu, H. Giessen, L. Dal Negro, M. Brongersma, T. Odom, H. Atwater, N. Zheludev, A. Zayats, M. Ford, M. Blaber, O. Muskens, M. Noginov, R. Soref, M. Wegener, M. Polini and other groups

A. Boltasseva and H.A. Atwater, Science **331**, 290 (2011)

G. Naik, V. ShalaeV, A. Boltasseva, Advanced Materials 25 (24), 3264 (2013)

C. Zhang et al., Advanced Materials, 1521, 2017; N. Kinsey et al, JOSA B **32**(1), 2015

METALS TO 'LESS-METALS'

- Reduce carrier concentration: Mixing them with non-metals \Rightarrow

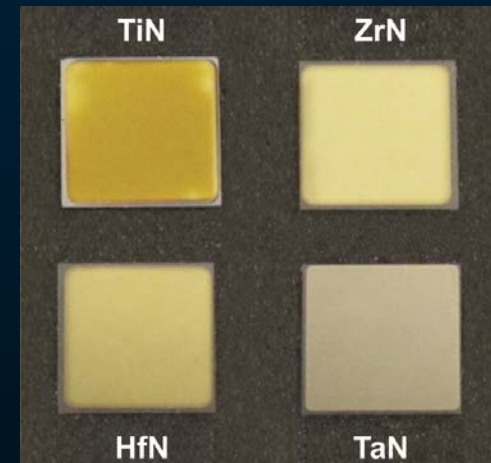
Many compounds:
Intermetallics
Ceramic materials

- Silicides
- Germanides
- Borides
- Nitrides
- Oxides
- Hydrides
- Metallic alloys



Wiki:

Ceramics = metal + non-metal



Transition metal nitrides

Mimic Au optical properties

High melting point!

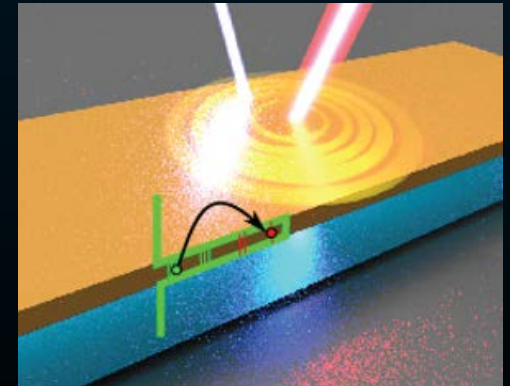
REFRACTORY

Hard materials

See work by E. Hu, H. Giessen, J. Dionne, G. Naik, H. Atwater, S. Ishii, M. Blaber, M. Ford, Soref, L. Dal Negro, A. Zayats, A. Calzolari, P. Patsalas and other

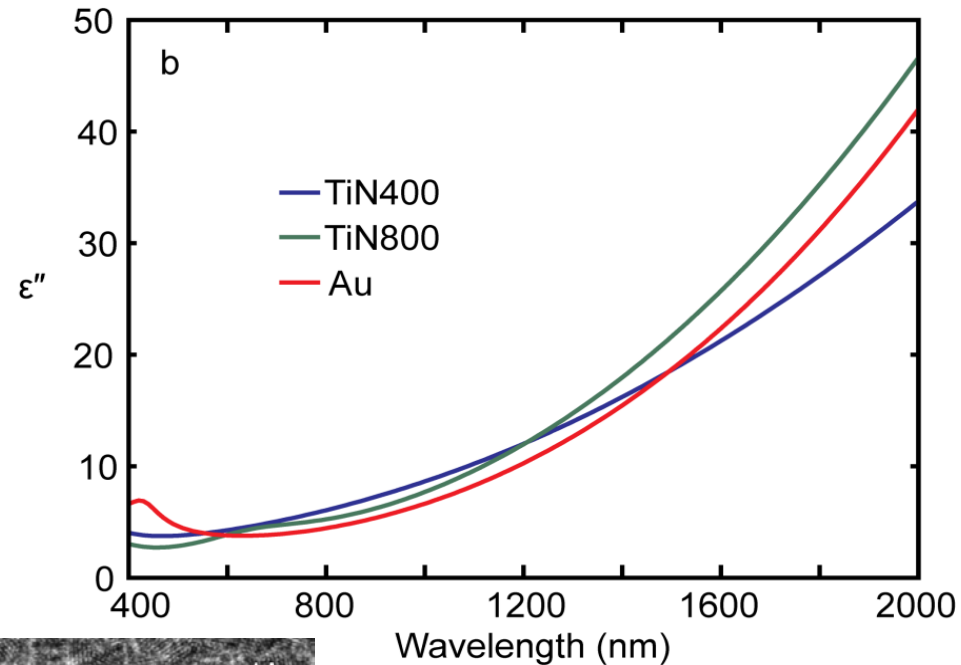
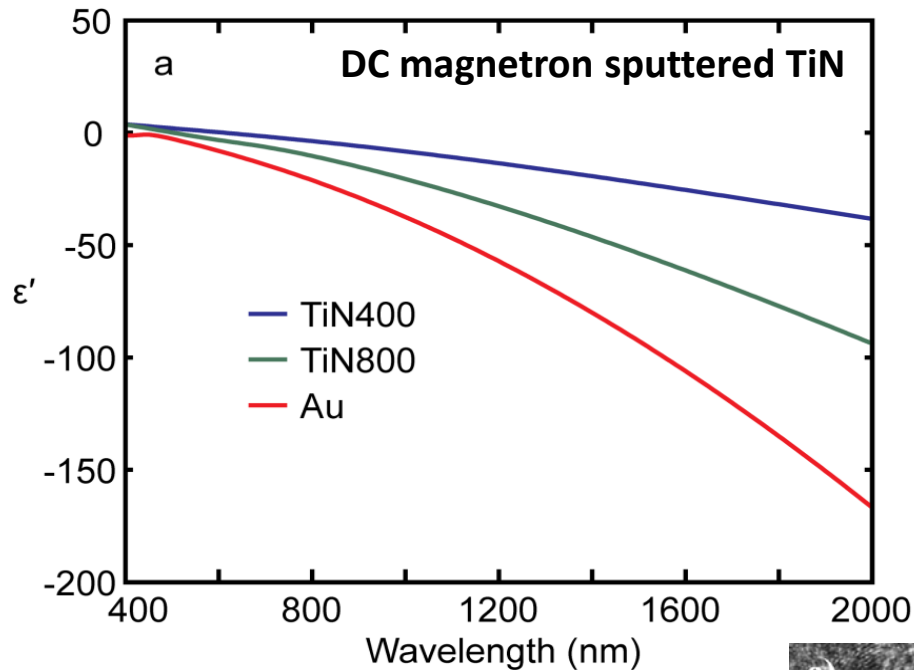
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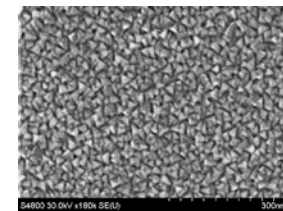
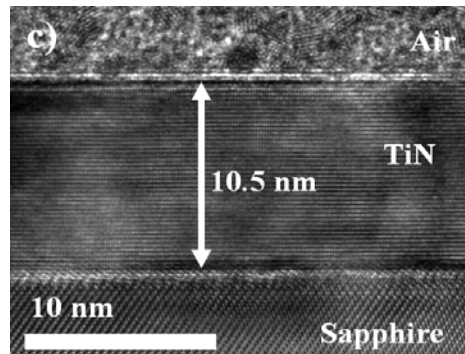
TITANIUM NITRIDE

Plasmonic, Tailorable, REFRACTORY



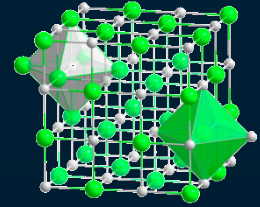
Ultra-thin/Smooth
Epitaxial growth

See work by L. Dal Negro, E. Hu, H. Giessen, J. Dionne, G. Naik, H. Atwater, S. Ishii and other

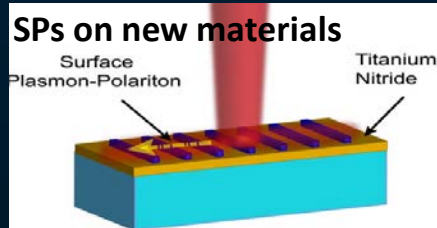
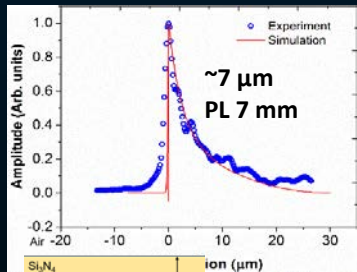
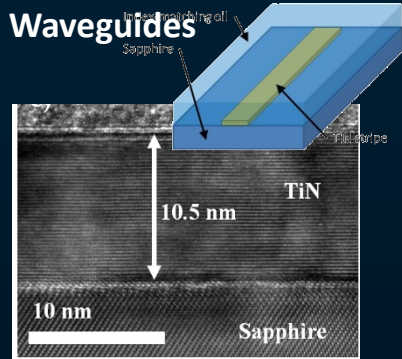


Crystalline TiN on c-Sapphire
(rms roughness 0.5 nm)

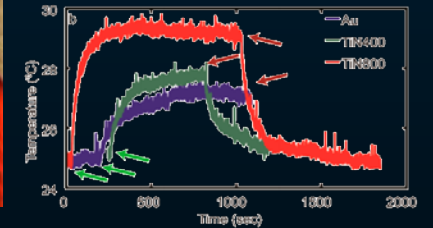
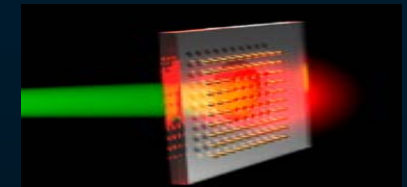
TMNs HIGHLIGHTS/RESULTS



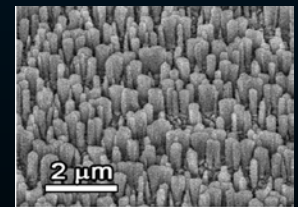
- New functional devices and new physics unlocked by tailorable **TMNs**
 - *Plasmonics/Metamaterials/Metasurfaces in VIS*
 - *Robust/high-T Stable/CMOS, bio-compatibility*



Editor's Choice
Development of epitaxial Al₂O₃/TiN for artificially structured metal/semiconductor superlattice metamaterials
Bivas Saha, Somnath Saha, Gurraj V. Nair, Alexandra Bottasso, Eric A. Stech, Eric P. Kvam, and Timothy D. Sands



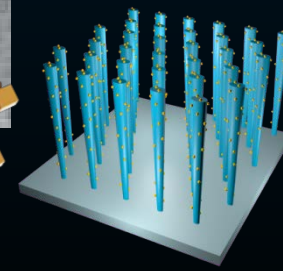
Local heating



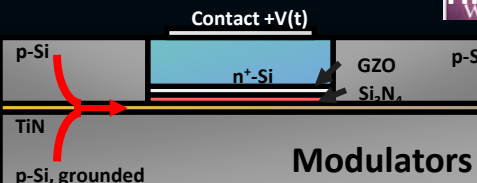
- AdvMat 2016
- NanoLet 2013
- MatToday 2014
- AdvOptMat 2017



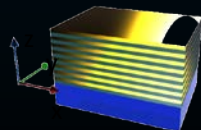
TiO₂-TiN



Catalysis



Modulators

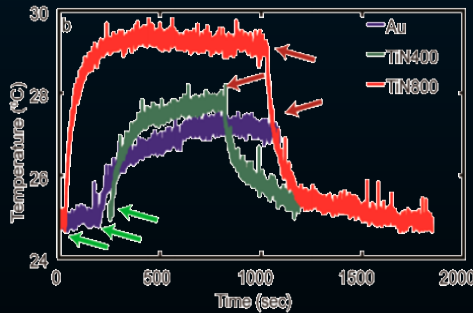
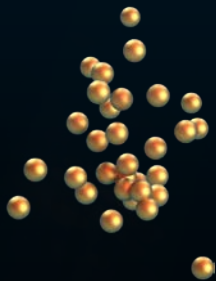


- OMEx 2012
- PNAS 2014
- AdvMat 2013
- LPR 2014

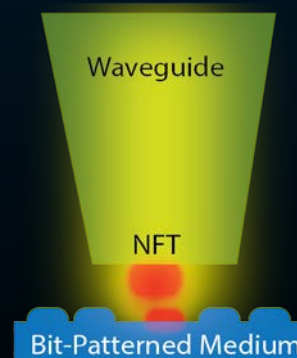
POTENTIAL OF PLASMONIC CERAMIC MATERIALS

Ceramic (high-T stable) materials with plasmonic properties

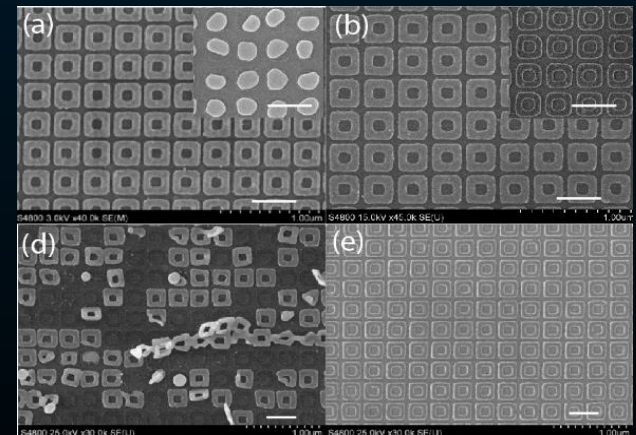
- Photothermal biomed apps/therapy/drug delivery
- Heat-assisted magnetic recording
- Harsh environment sensing
- Solar/Thermophotovoltaics (S/TPV)
- Plasmon-assisted photocatalysis
- Optical trapping/nanomanufacturing



Nano Letters 2013



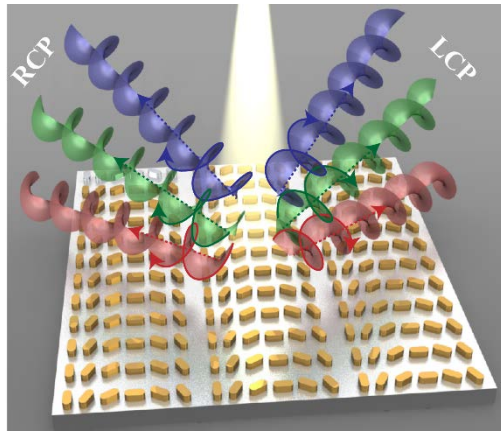
Faraday Discussions 2014



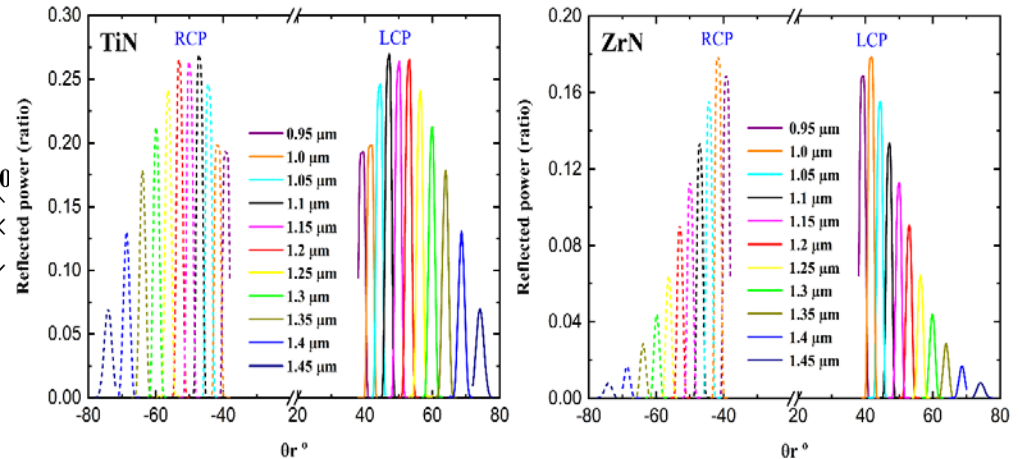
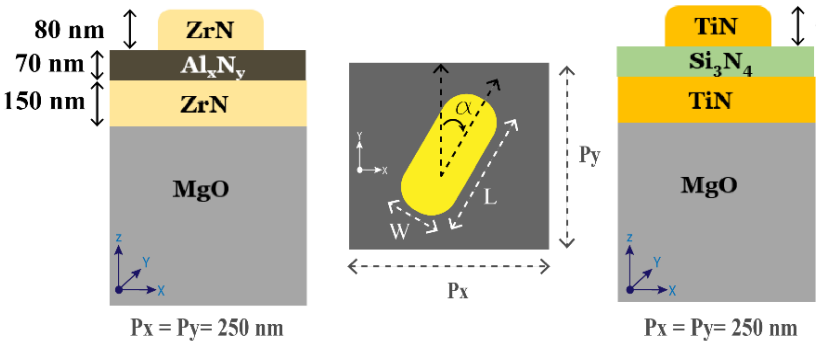
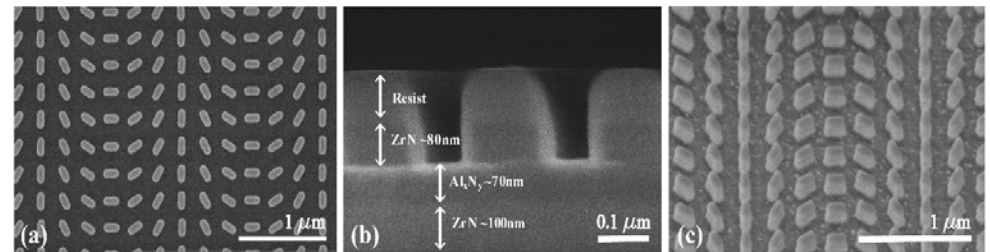
Mater. Today 2014

Photonic Spin Hall Effect in TiN Metasurface

Photonic SHE: Reflects the two photonic spins (left and right circular polarizations, LCP and RCP) in opposite directions with ROBUST Nitrides



All-nitride: highly anisotropic, multilayer resonators

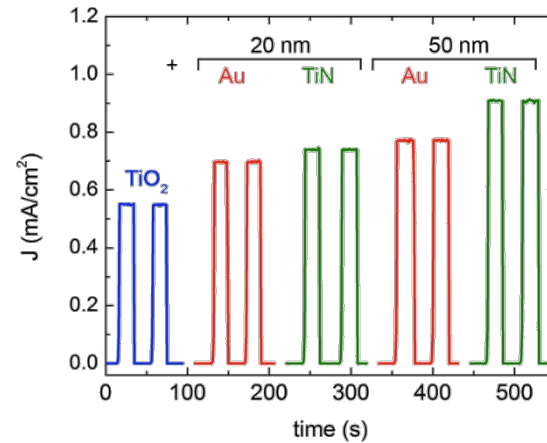
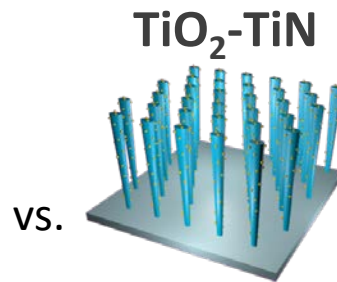
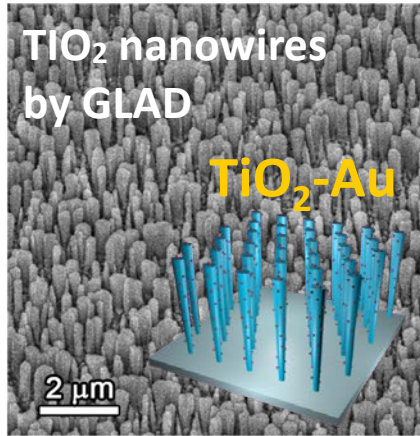


Phase gradient for the two opposite polarizations, created by anisotropic antenna unit cells
Reflection mode unit cell supporting gap-plasmon type resonance

See work by X. Zhang, F. Capasso, E. Hasman, and other

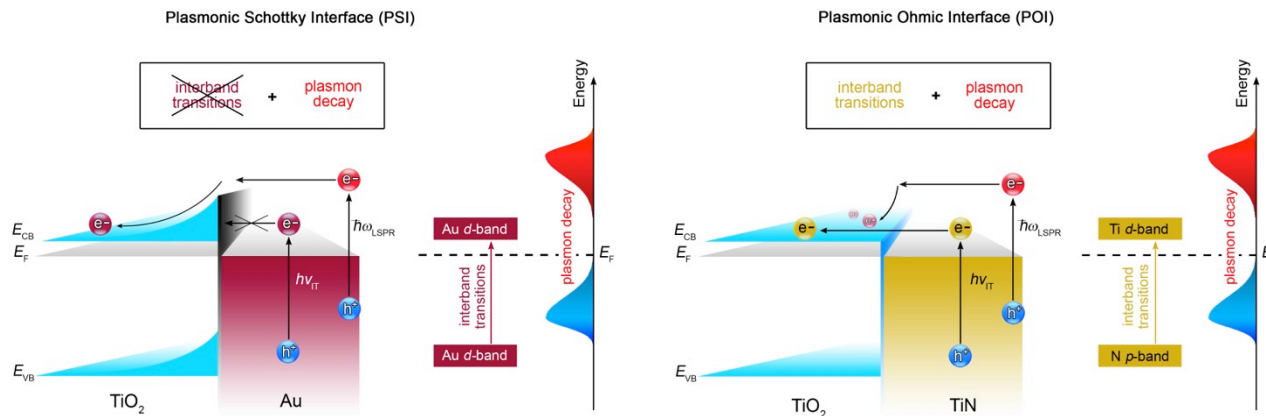
PLASMON-ENHANCED WATER SPLITTING

Enhancing hot electron collection with TiN nanoparticles



TiN and Au NPs:
TiN produces higher photocurrent enhancement than Au NPs!

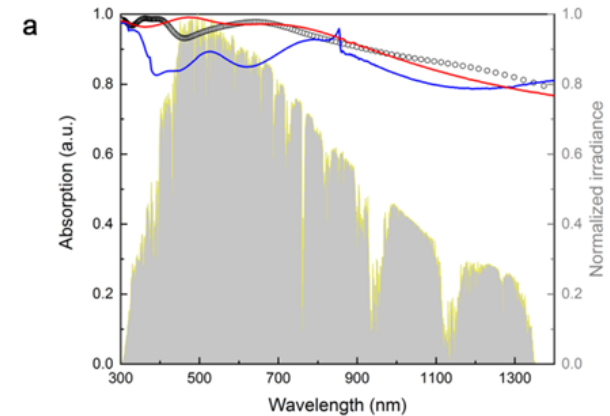
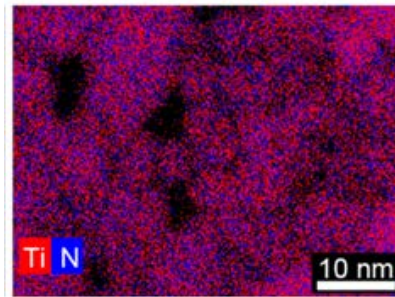
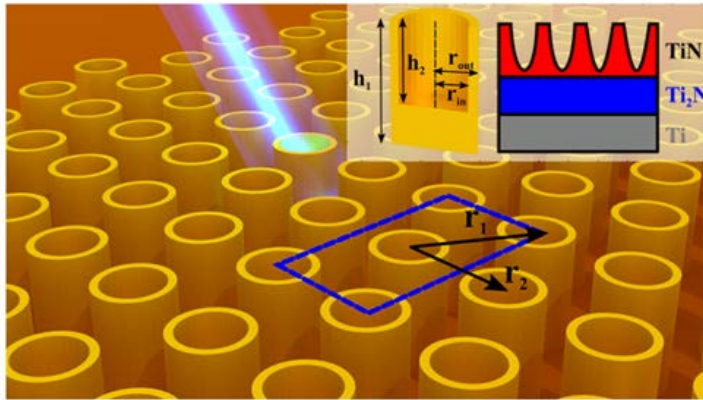
TiN has a broader LSPR and produce more hot electrons than Au, higher transmission of hot electrons at the interface with TiO₂



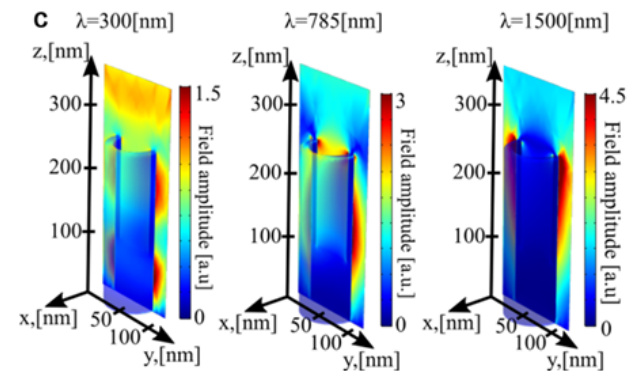
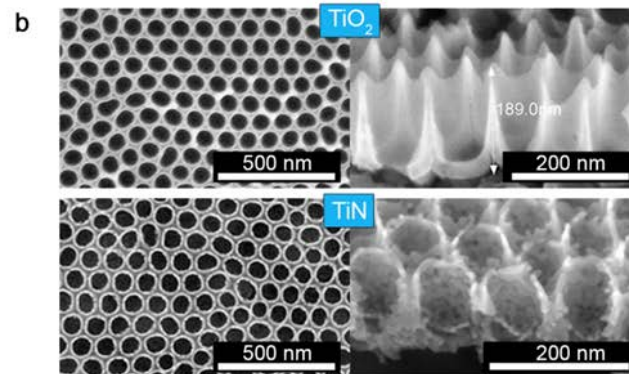
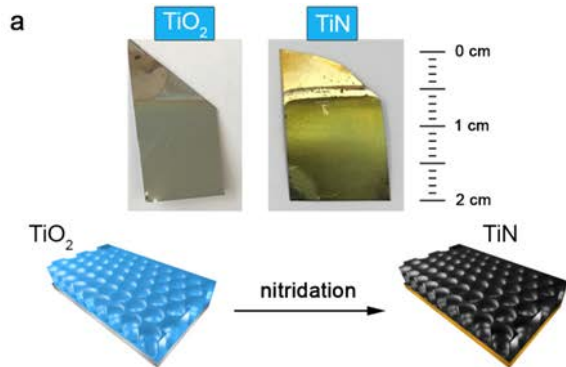
With A. Govorov

THERMOPLASMONIC TiN NANOFURNACE

- High temperatures can be obtained using thermoplasmonic TiN nanofurnace under solar illumination
- Enables thermally induced nanochemistry with attolitre volume precision

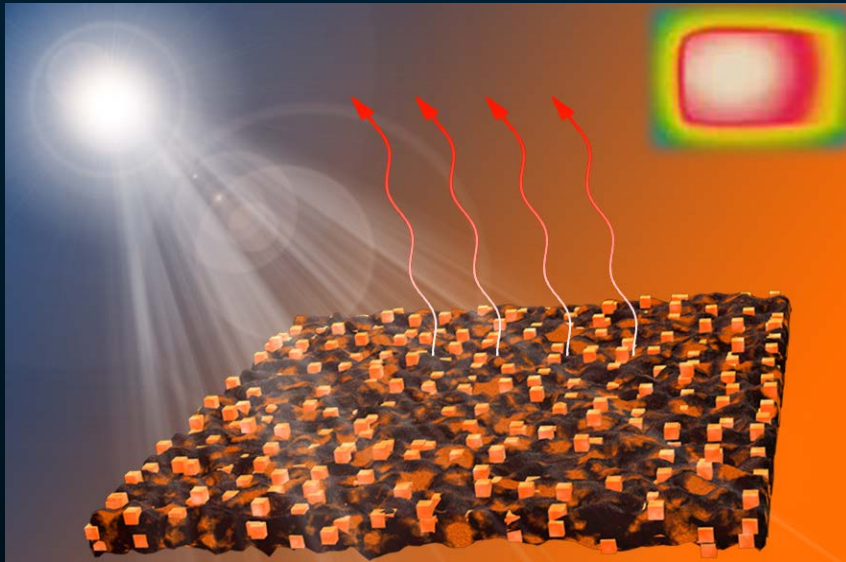


TiN nanofurnace formed by nitridation of TiO_2 at 600°C

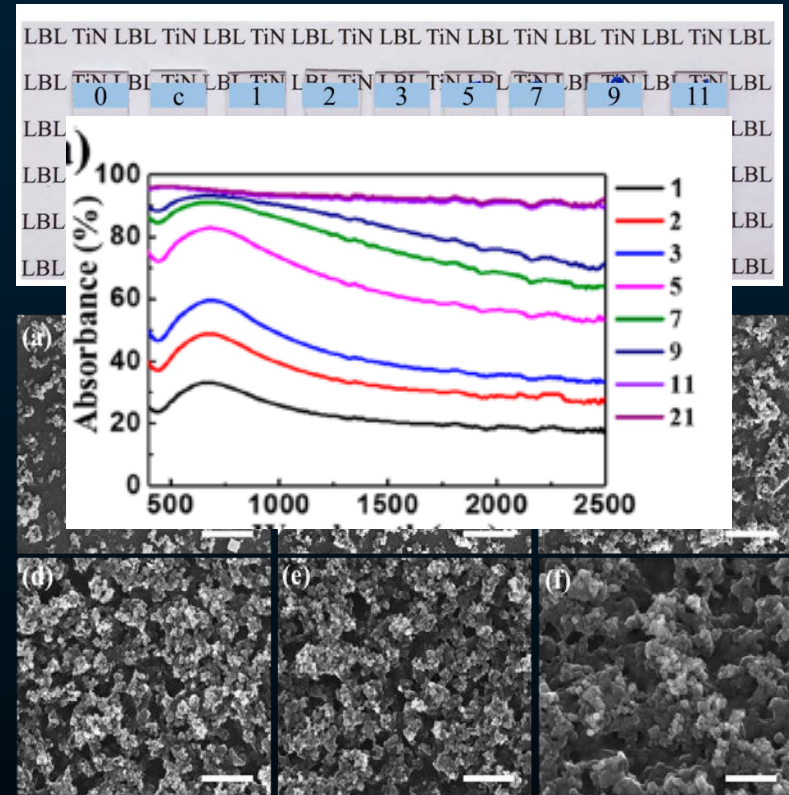


Biomimetic TiN as Broadband Absorbers

Plasmonic Biomimetic Nanocomposite with Spontaneous Subwavelength Structuring as
Broadband Absorbers



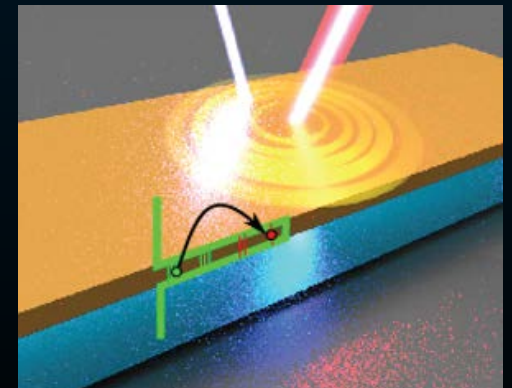
Corrugated TiN coatings:
Broadband absorption (90%)
FAST, FLEXIBLE, ENVIR. FRIENDLY



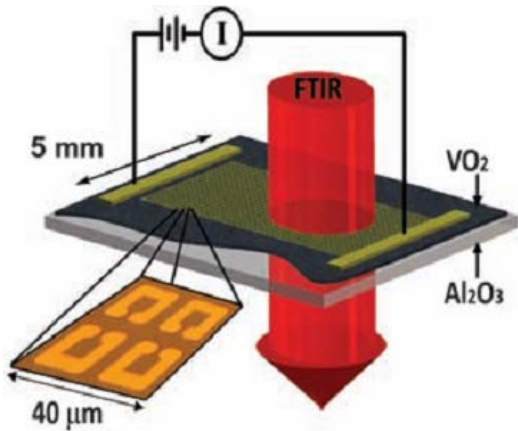
Layer-by-layer assembly of TiN nanoparticles with polyelectrolytes: out-of-plane topography with subwavelength dimensions.

OUTLINE

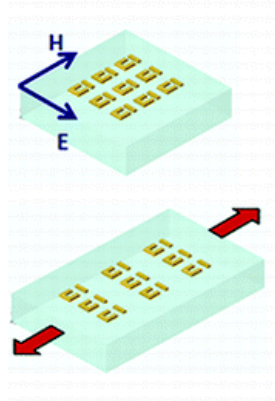
- Plasmonics: Loss and Gain
- Expanding Materials Playground for Plasmonics and Nanophotonics
- Metal Nitrides
- **Transparent Conducting Oxides**
- **Material Requirements: Tunability & T-Stability**
- Ultra-Thin Plasmonic Metal Nitrides
- MXenes: Novel Quasi-2D Materials
- Outlook



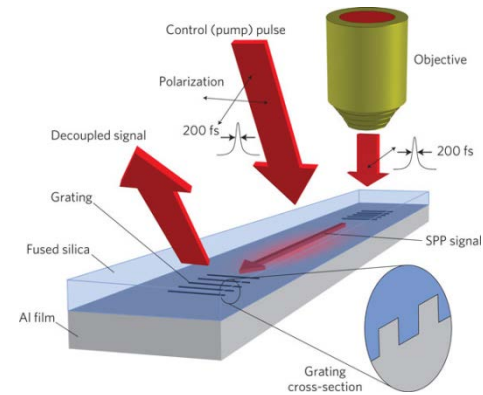
APPROACHES TO SWITCHING/TUNING



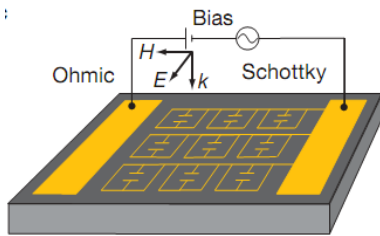
Phase Transition in VO_2 ¹



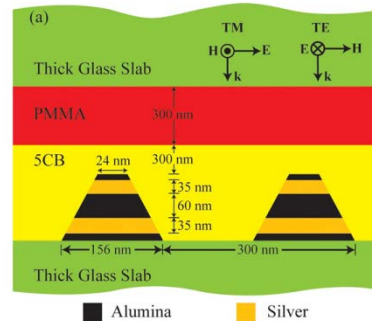
Mechanical Stretching²
"Plasmomechanics"
Electromechanical



Optical Control³



Electrical Injection
in Semiconductors⁴



Liquid Crystals⁵

Key issues

- Speed vs Magnitude
- Electrical control
- Modulation in VIS/NIR
- Tunable plasmonic materials

¹T. Driscoll et. al., Science (2009)

³K. F. MacDonald et. al., Nat. Phot. (2008)

⁵S. Xiao et. al., APL (2009)

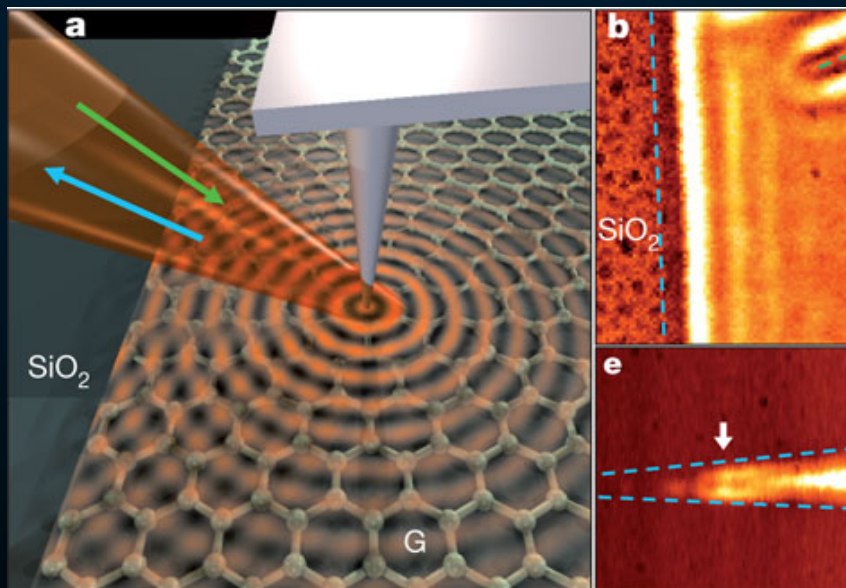
²I. M. Pryce et. al., Nano Lett. (2010)

⁴H. T. Chen et. al., Nature (2006)

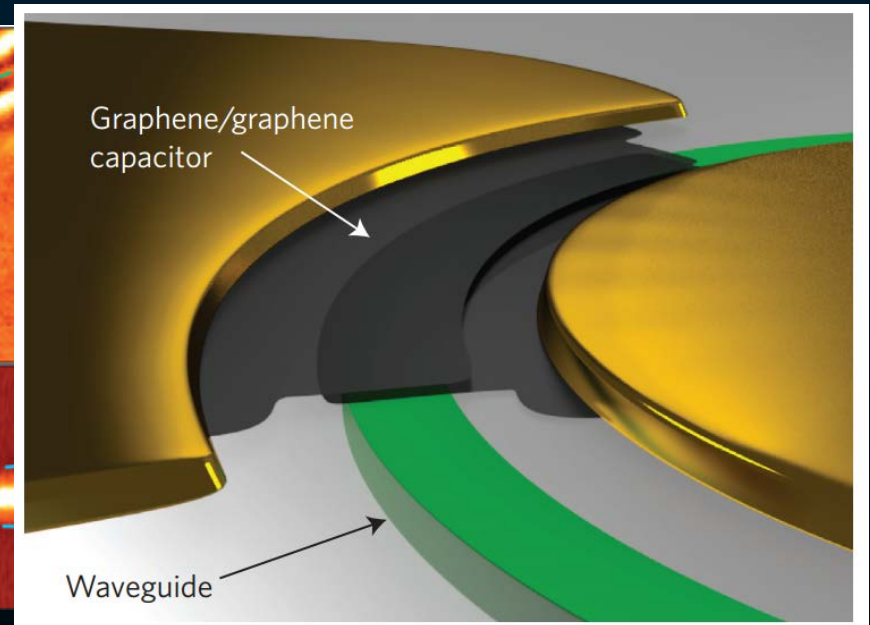
Zheludev, Atwater, Brongersma, Mortensen, other

GRAPHENE AS TUNABLE PLATFORM

- High degree of optical confinement – **PLASMONIC MATERIAL**
- Easy and high dynamic tunability – **TUNABLE PLATFORM**
- Stackable with other 2D materials for new properties
- Zero bandgap, uniform optical absorption – a promising material for photodetection



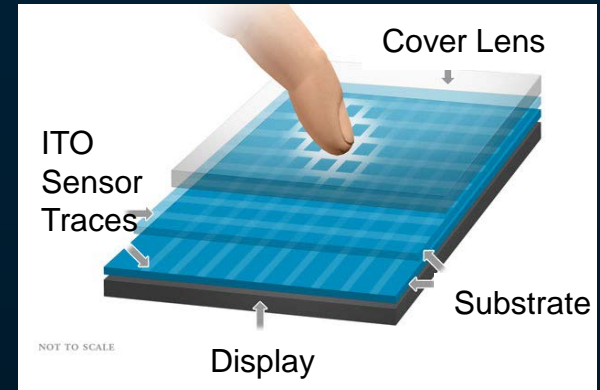
Graphene plasmons in IR
Z. Fei et al, Nature (2012)



C.T. Phare, ...& M.Lipson, Nature Photonics (2015)

TCOs AS DYNAMIC MATERIALS

- Transparent Conducting Oxides with extremely high dopant solubility (10^{21} cm^{-3})
- Indium Tin Oxide (ITO)/Doped Zinc Oxide/Vanadium Oxide/Cadmium Oxide
- Numerous advantages for photonics
- Mature fabrication processes
 - Sputtering, PLD, ALD, CVD, etc.
- Non-stoichiometric materials
 - Plasma frequency highly tunable from VIS to NIR
- Ultra-fast response
- Electrical- and all-optical switching



ITO-based touch screens

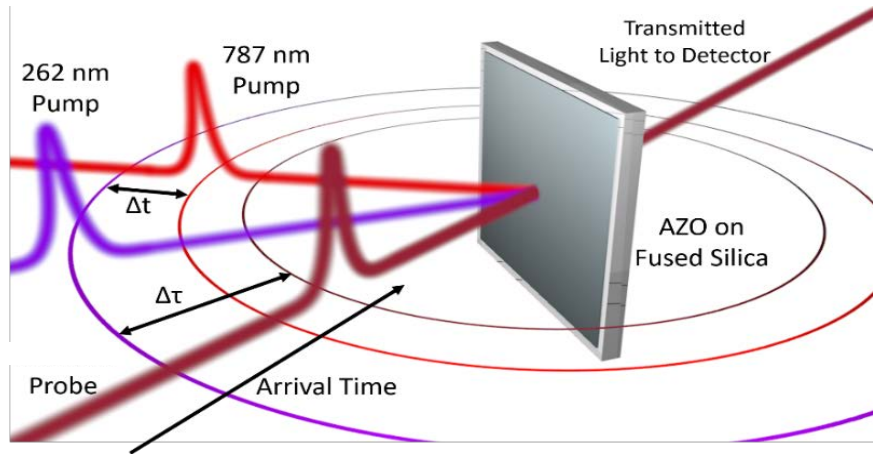


IGZO-based highly resolved flexible screen

G.V. Naik et al, Opt. Mater. Express 1(6), 2011

Also work by H. Atwater, R. Boyd, H. Li, O. Muskens, M. Brongersma, I. Brener, H. Li, N. Zheludev and other

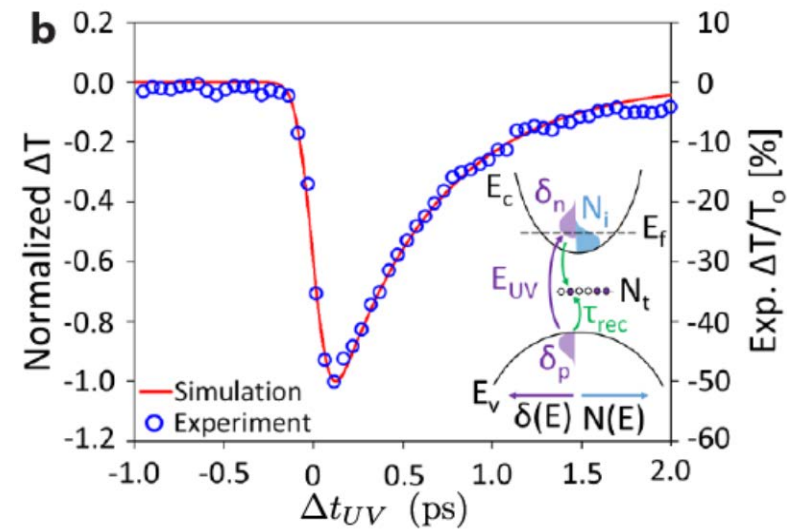
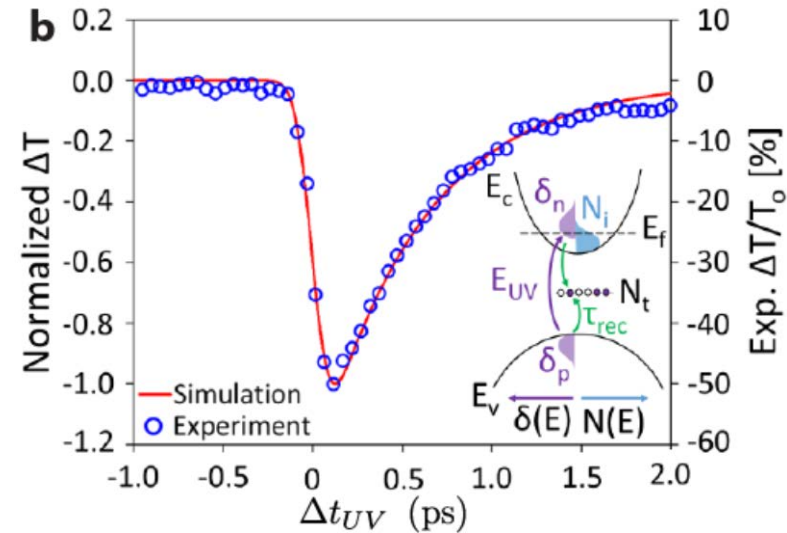
ULTRAFAST NONLINEARITIES



Engineered nonlinearities by controlling delay between two pumps: UV (262nm) and IR (787 nm)

Strong modulation with change in T/R $\sim 100\%$
With ultrafast response ~ 100 fs

fast NLOs – see also work by Zheludev group
NLO in TCOs – see also work by Muskens group



ENZ ENHANCED NONLINERITIES

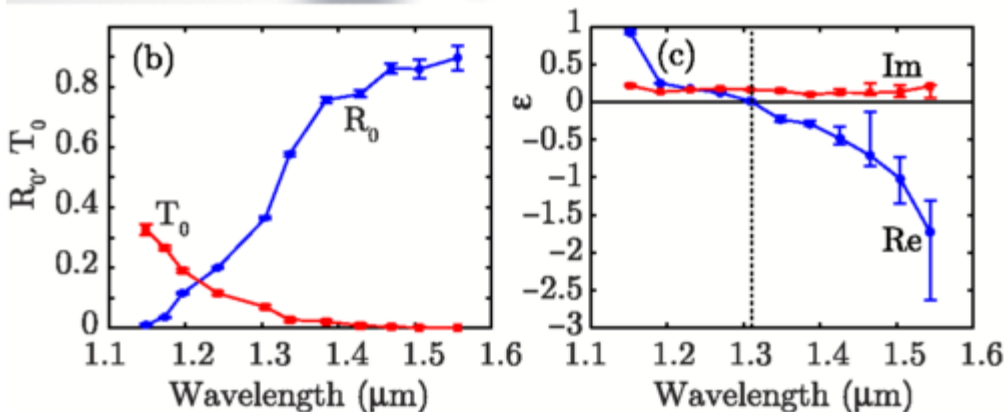
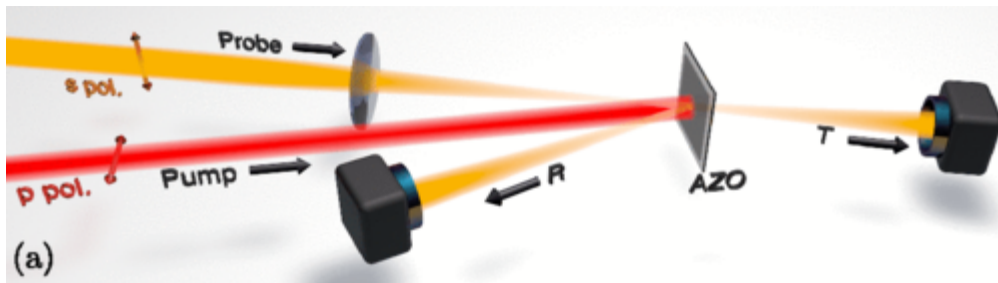
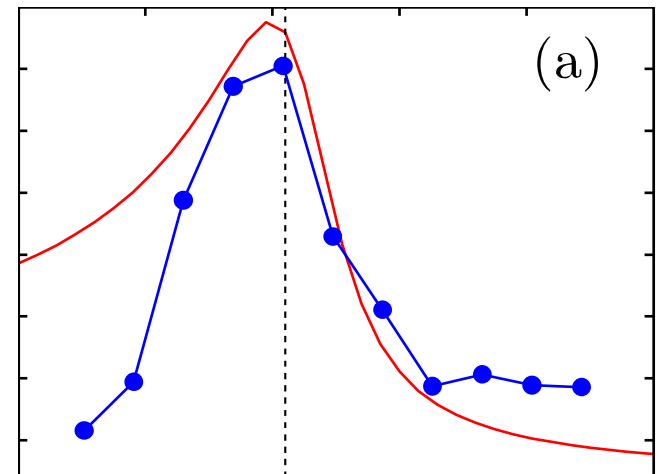
$$n = n_0 + \Delta n = n_0 + n_2 I$$

$$n_2 = n_{2r} + i\beta_2 \sim \frac{\chi^{(3)}}{n_0}$$

Kerr index is dependent on refractive index

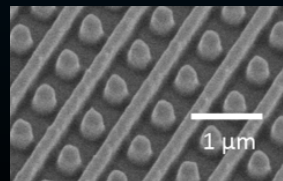
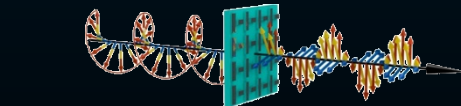
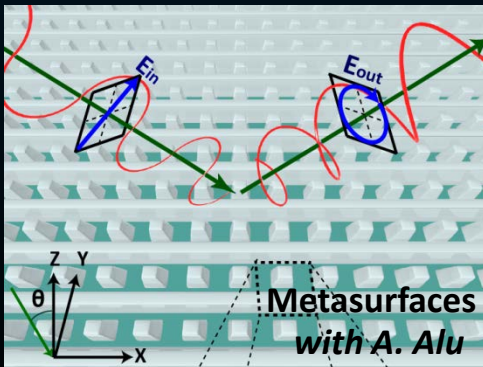
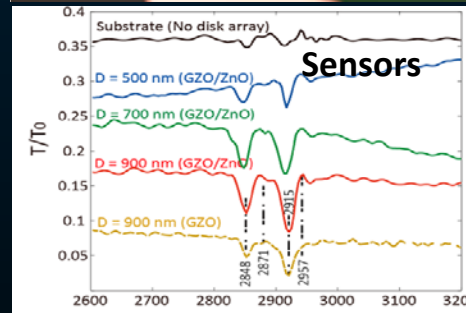
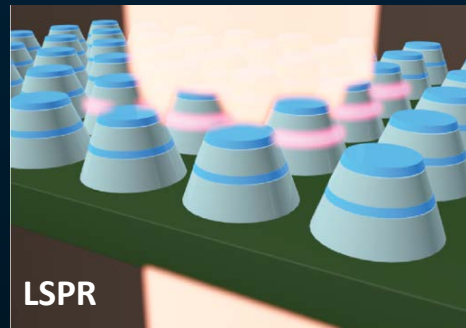
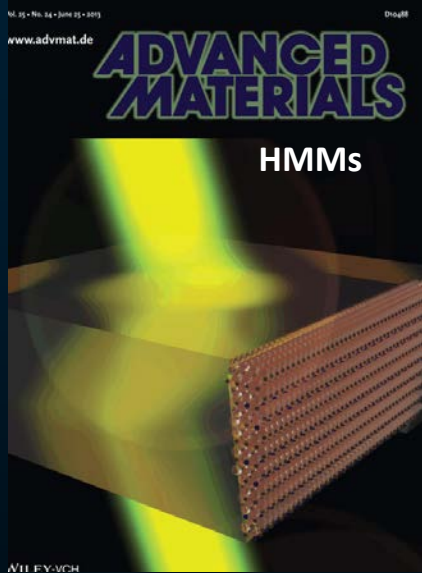
- $n_2 \sim \chi^{(3)}/n_{probe}$ (non-degenerate)
- $n_2 \sim \chi^{(3)}/n_{probe}^2$ (degenerate)

Collaboration with Heriot-Watt Univ.

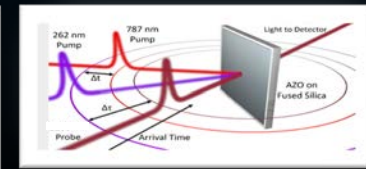
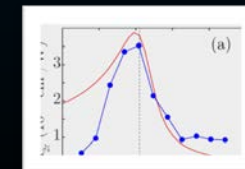
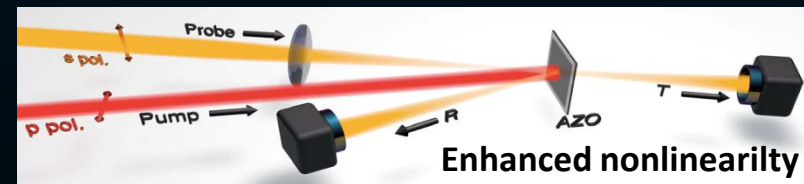
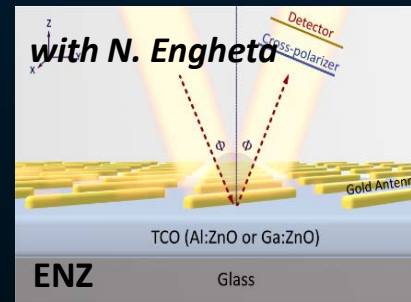
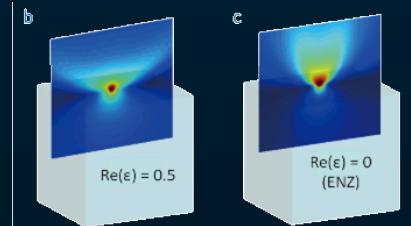
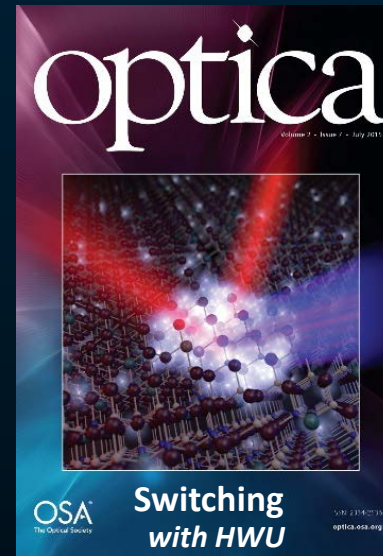


TCO HIGHLIGHTS/RESULTS

- New functional devices and new physics unlocked by LOW-LOSS TCOs
 - Plasmonics/Metamaterials/Metasurfaces in NIR
 - Ultra-fast switching/Enhanced Nonlinearities



IEEE-JSTQE 2013
PNAS 2012
AdvMat 2013
ACS Ph 2015
ACS Nano 2016

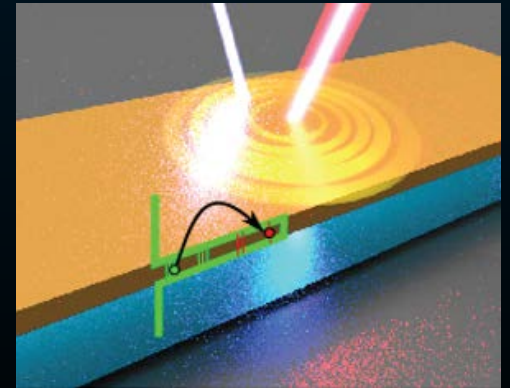


with HWU

Optica 2016
Optica 2016
PRL 2016
NatCom 2017

OUTLINE

- Plasmonics: Loss and Gain
- Expanding Materials Playground for Plasmonics and Nanophotonics
- Metal Nitrides
- Transparent Conducting Oxides
- Material Requirements: Tunability & T-Stability
- **Ultra-Thin Plasmonic Metal Nitrides**
- MXenes: Novel Quasi-2D Materials
- Outlook

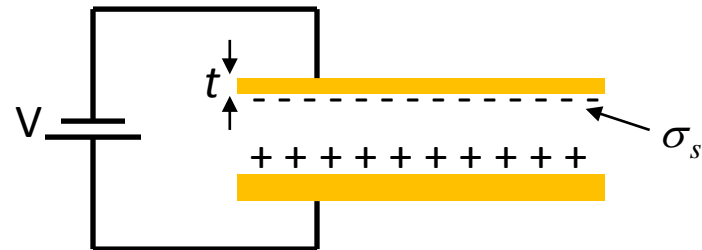


TUNING THE PROPERTIES OF METALS?

- High carrier density in metals: no appreciable tuning

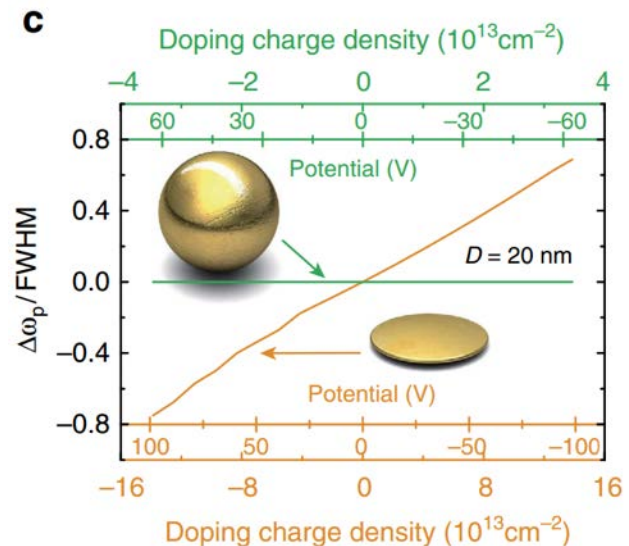
- Change in the carrier density

$$\Delta n = \frac{\sigma_s}{t}$$



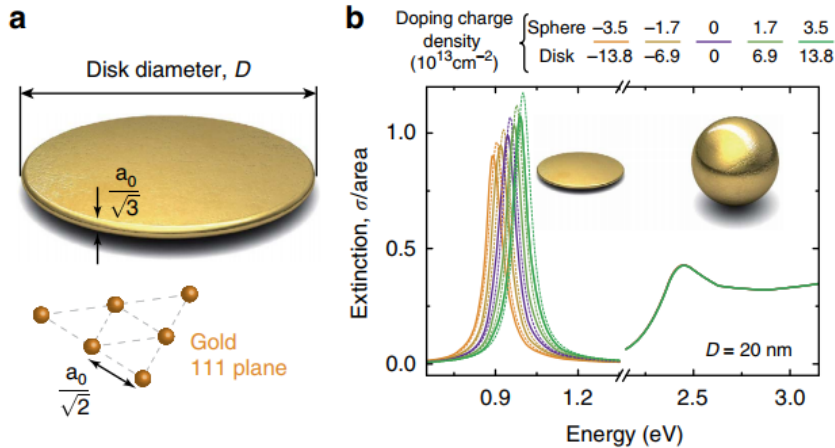
- Thinner the film larger the tunability!

- Tuning of carrier density close to 15-20% has been theoretically predicted in atomically thin films



ULTRA-THIN PLASMONIC FILMS

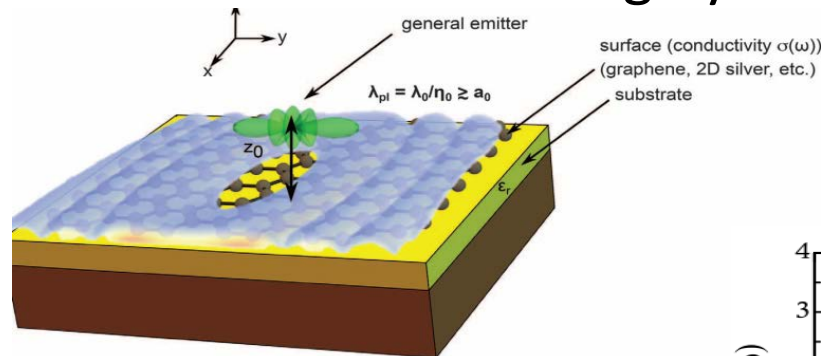
- Electrical (optical) control over the properties



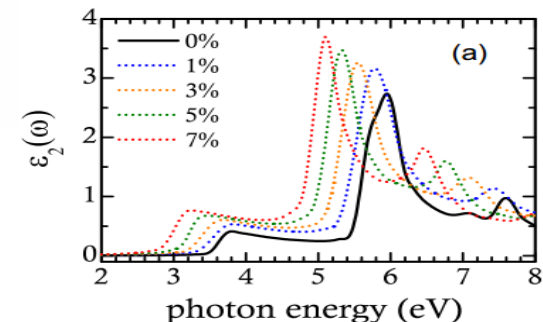
J. Garcia de Abajo's group
Nature Communications, 2014

- Unique light-matter interactions in highly confined light regime

M. Soljagic's group
Science 2016

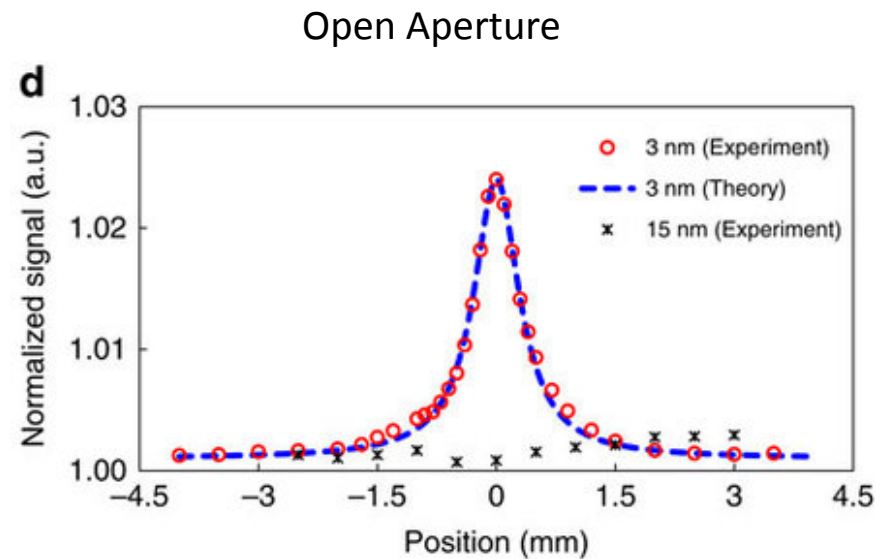
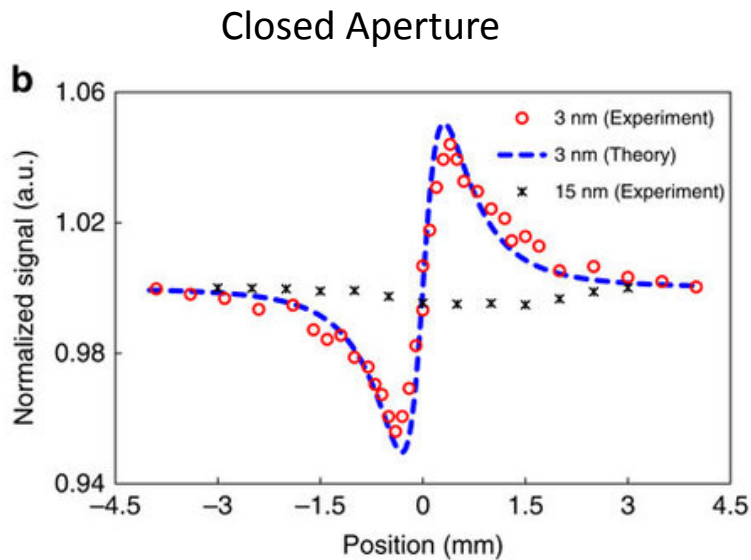
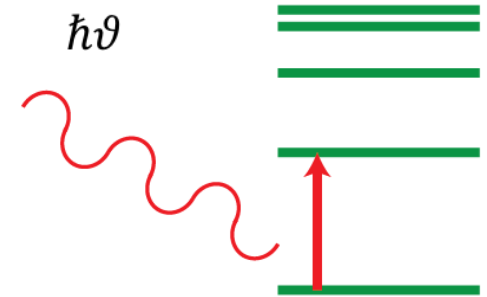


- Control the optical properties by adjusting strain/stress



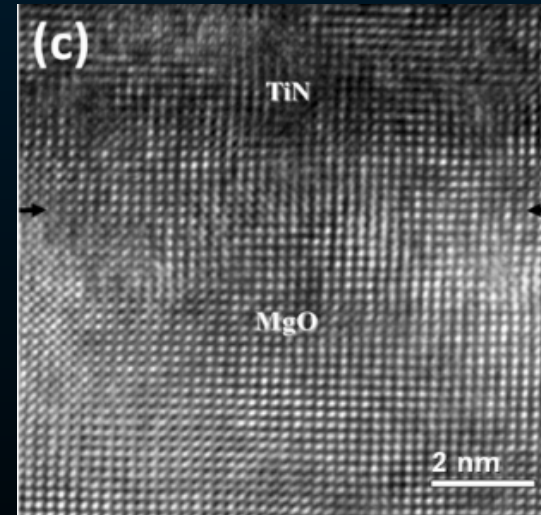
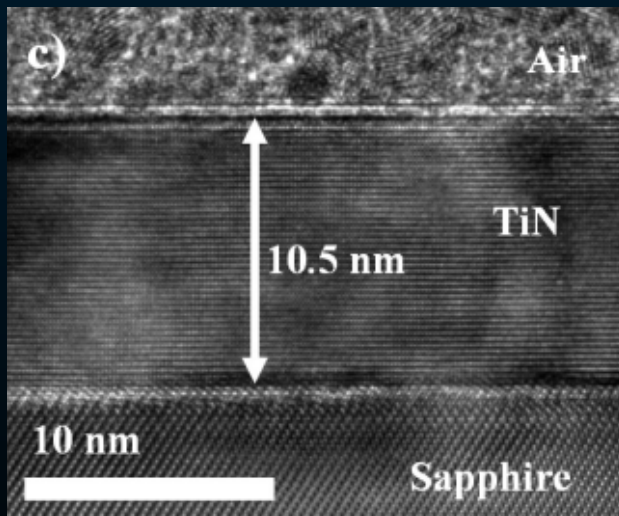
QUANTUM CONFINEMENT ENHANCED NONLINEARITIES

- Energy level discretization enhanced nonlinearities
- Enhanced nonlinear properties have been shown in Au quantum wells



PLASMONIC ULTRATHIN TiN FILMS

- Plasmonic noble metals
 - Difficult to grow smooth, continuous films <7-10nm
- Titanium Nitride
 - *Epitaxial growth* on c-sapphire and MgO
 - Potentially epitaxial growth of *ultrathin* (~1-2nm) films on Si
 - Enhanced nonlinearities
 - *High T- and High-Intensity Stability* and Robustness

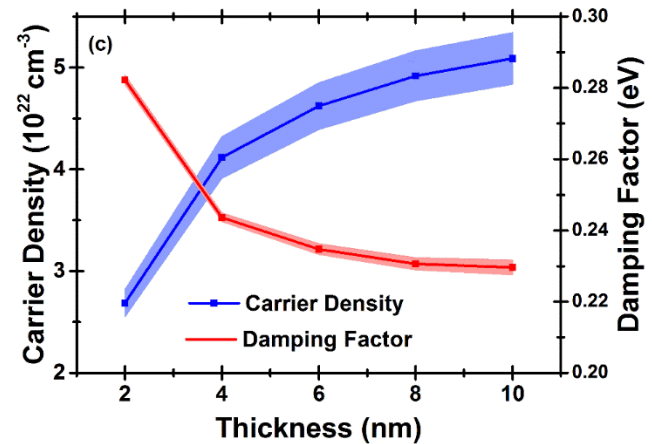
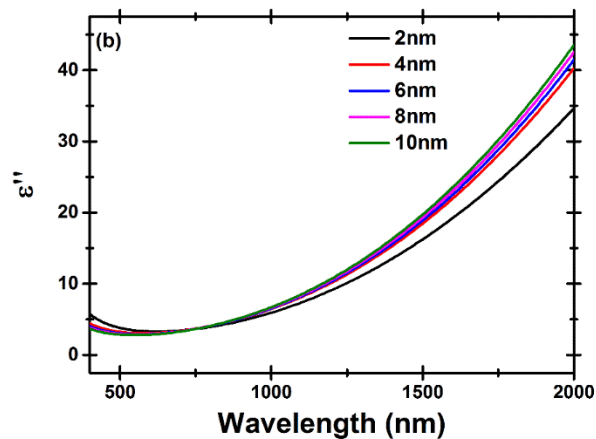
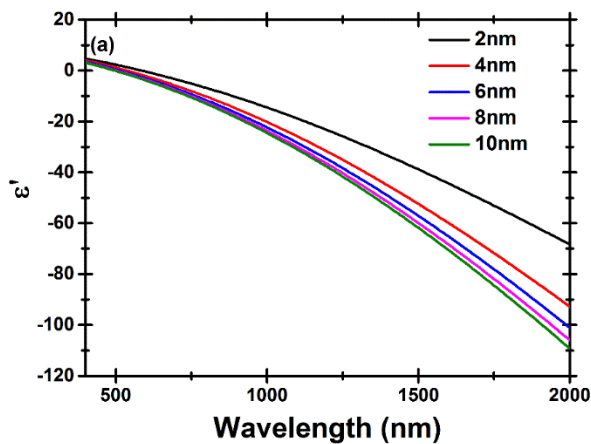


N. Kinsey et al., Opt. Express (2014)

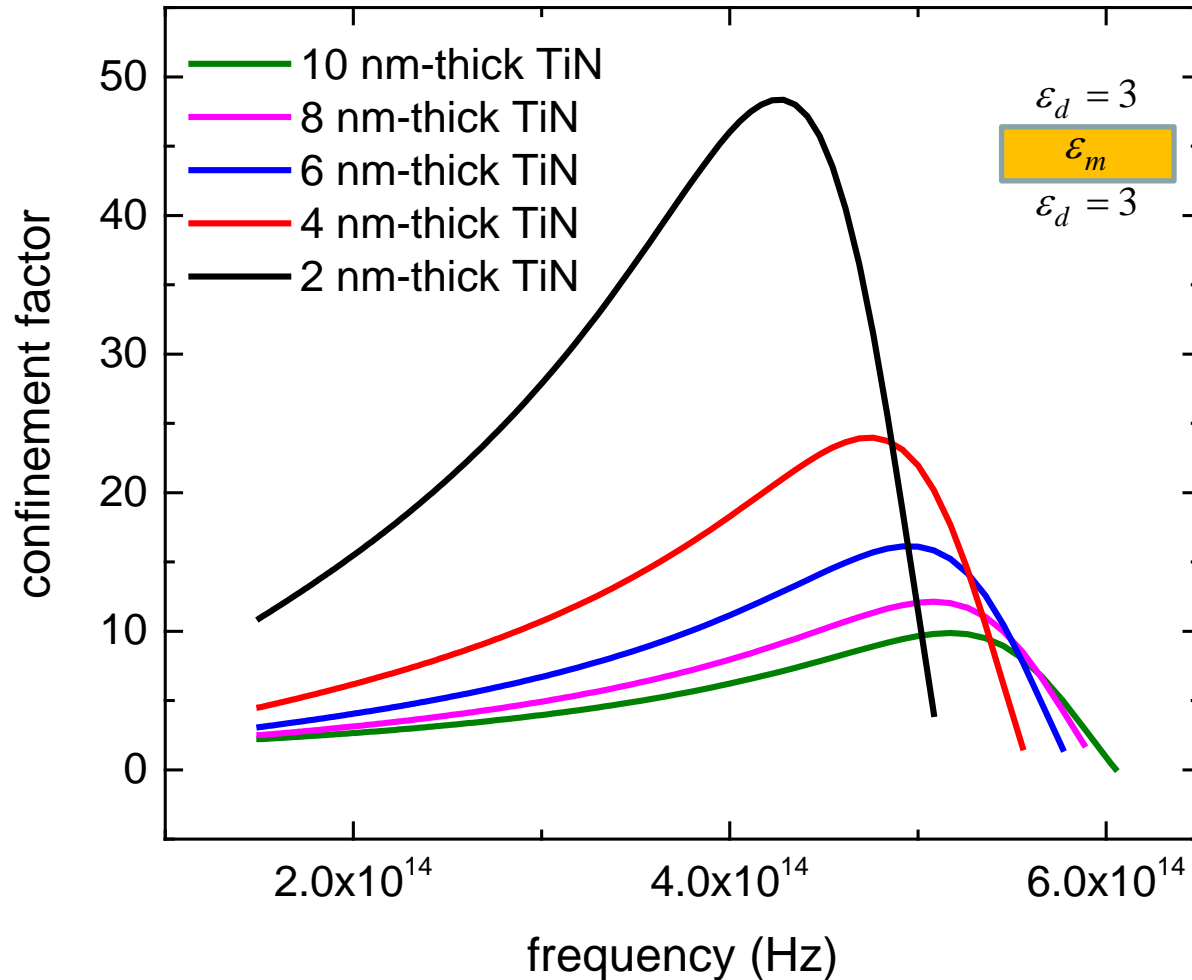
Chen et al., Nanoscale Research Letters (2014)

OPTICAL PROPERTIES OF ULTRATHIN TiN

- Lower metallicity (~ 2 -nm-thick TiN_xO_y layer on the surface)
- Agrees with theory; plasma frequency acquires the spatial dispersion ($\sim 2\text{D}$)
- Films remain highly metallic, even at a thickness of 2 nm ($n \approx 10^{22} \text{ cm}^{-3}$)
- Higher losses in thinner films
- Increase in scattering rate
 - Defect scattering: TiN_xO_y layer
 - Surface scattering rate, $\Gamma_{ss} \sim 1/t$, t = film thickness

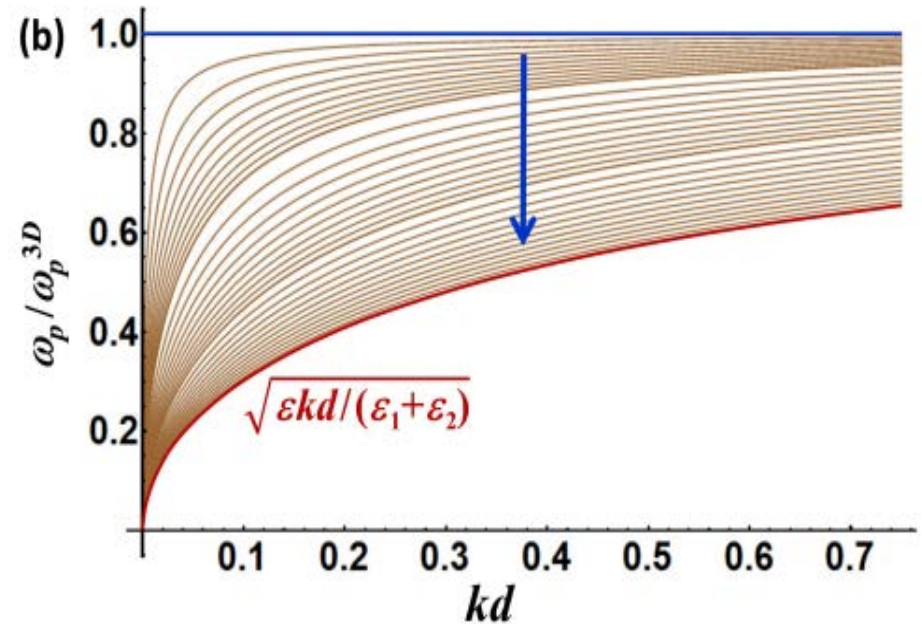
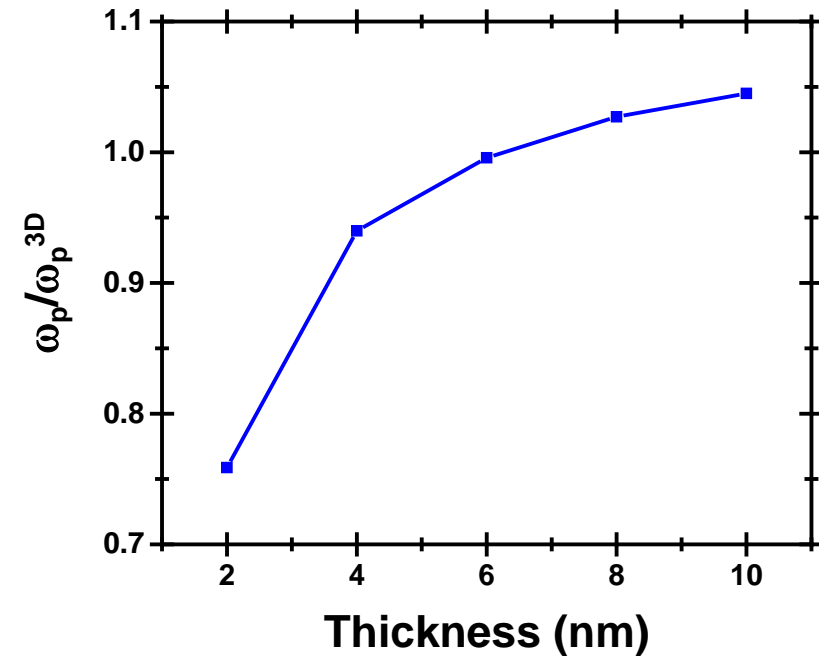


CONFINEMENT FACTOR CALCULATIONS



- Computed confinement factor of tightly confined plasmons λ_0/λ_p
- Maximum confinement of close to 50 in 2 nm films

EFFECT ON PLASMA FREQUENCY



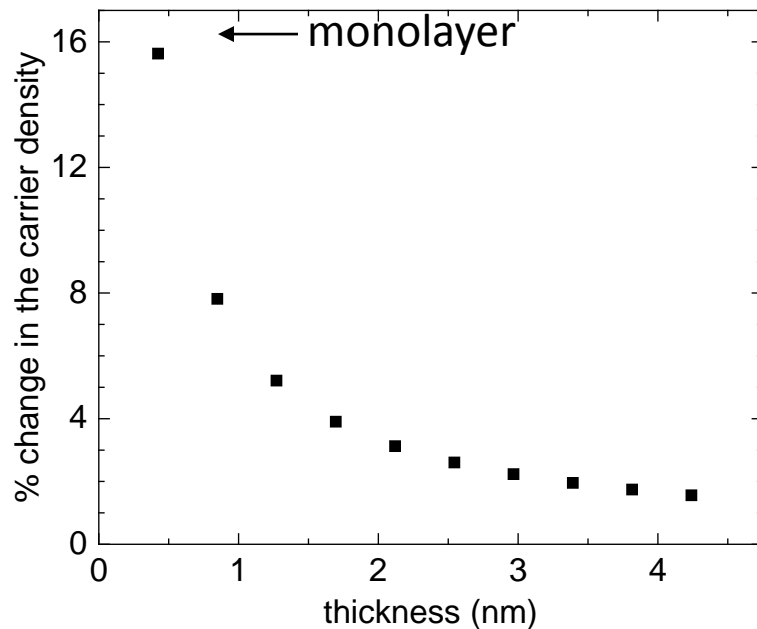
The plasma frequency acquires the spatial dispersion \sim typical for 2D materials:
shifted to the red at all fixed k with dielectric losses enhanced as the film thickness $d \downarrow$

$$\omega_p = \omega_p(k) = \frac{\omega_p^{3D}}{\sqrt{1 + (\epsilon_1 + \epsilon_2)/\epsilon kd}}$$

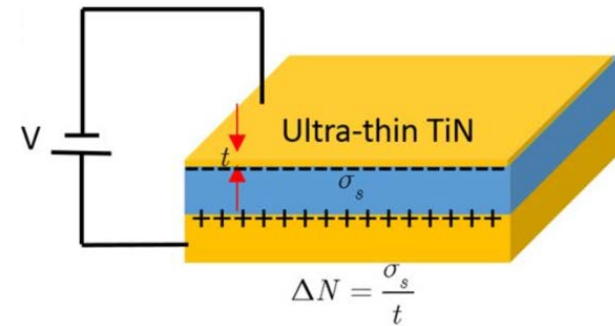
ULTRATHIN TiN: TUNABLE METAL?!

- Epitaxial quality films with thicknesses down to 1 nm are fabricated

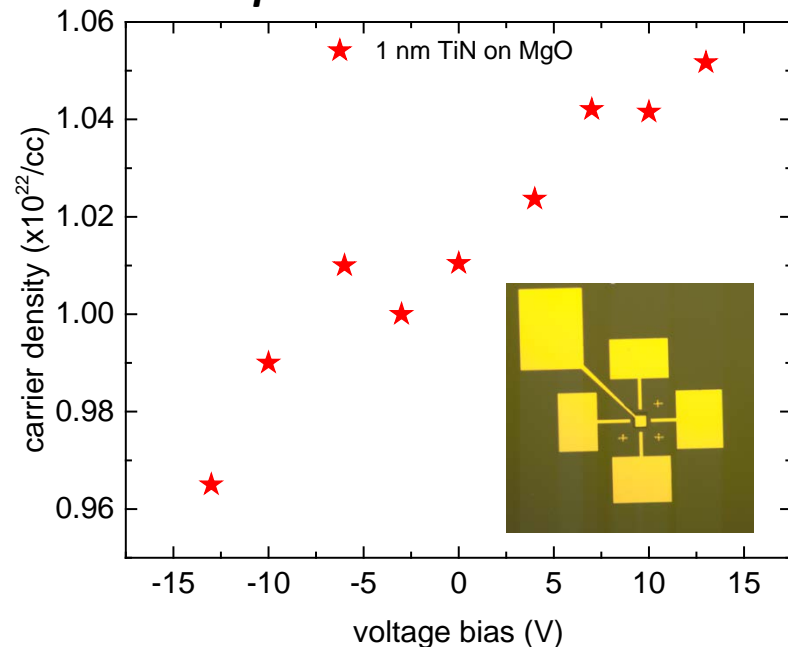
Calculation



- Close to 16% relative change in the carrier density is expected in monolayer TiN film
- Inversely proportional to film thickness



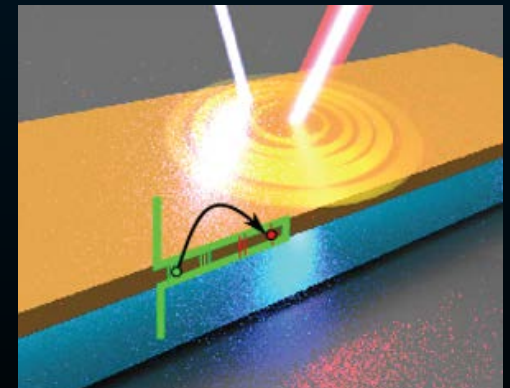
Gate dependent Hall measurements



8.5% change in 1nm TiN films!

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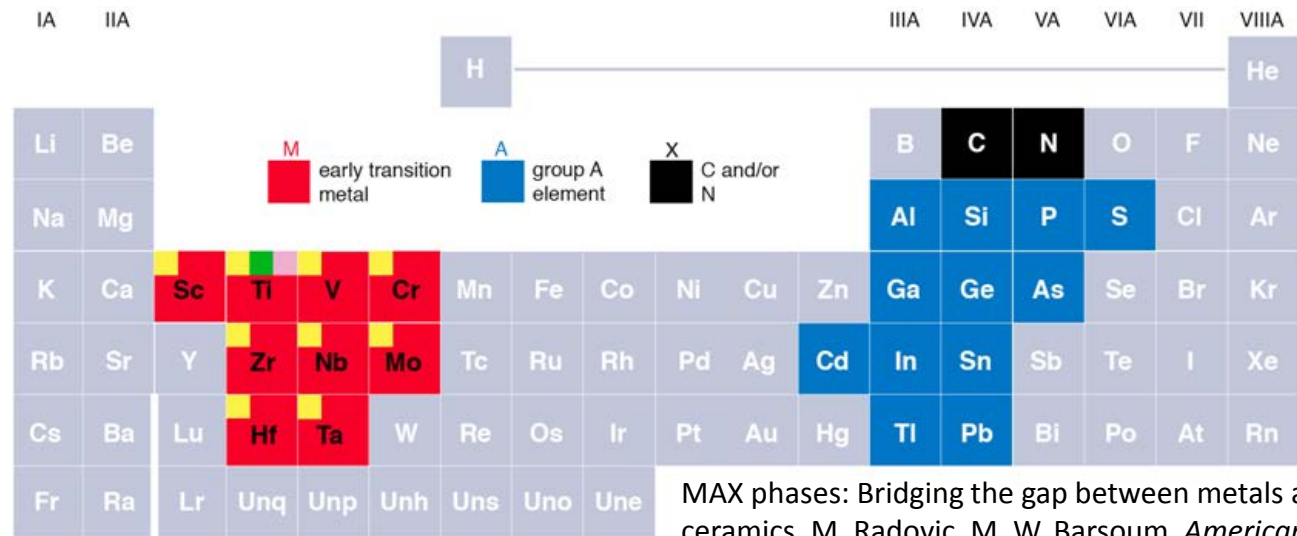
MAX Phases

The MAX Phases: a family of ternary carbides with the general formula $M_{n+1}AX_n$

M is an early transition metal

A is an A-group element (mostly IIIA and IVA),

X is C and/or N

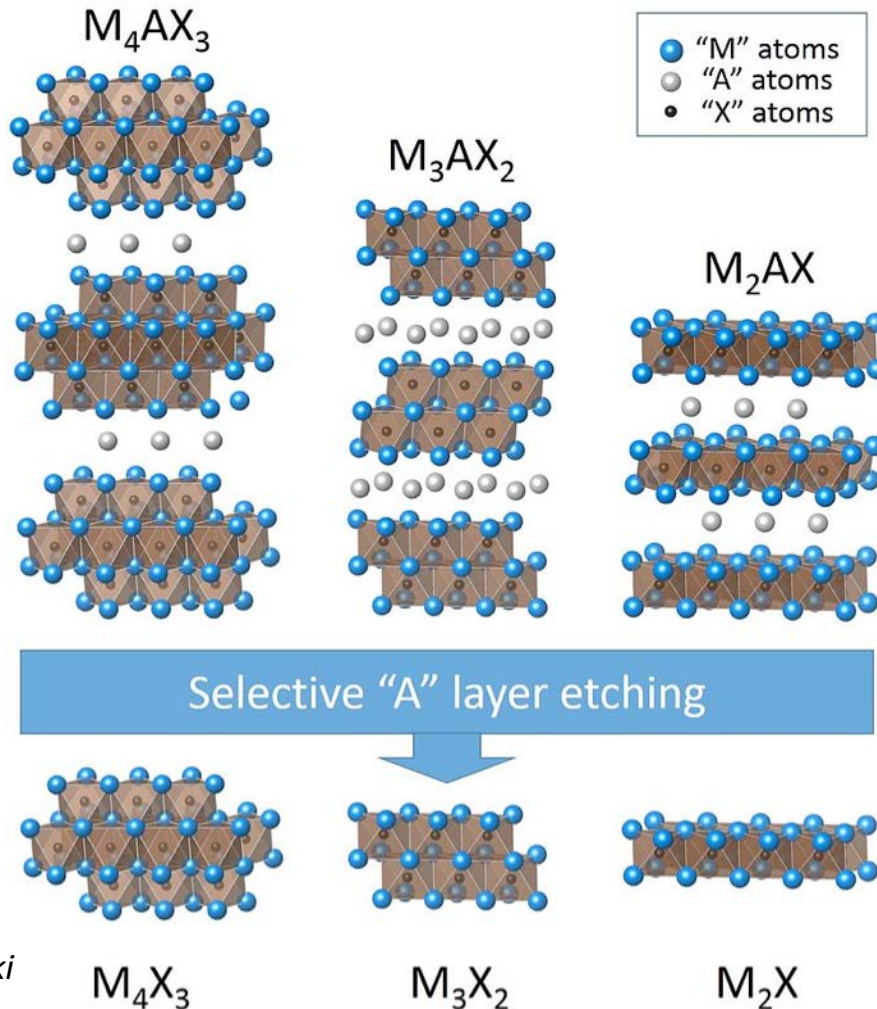


MAX phases: Bridging the gap between metals and ceramics, M. Radovic, M. W. Barsoum, *American Ceramic Society Bulletin* (2013)

- Unique, combination of properties: **METALS & CERAMICS**
- **Conduct heat and electricity** like metals
- **Elastically stiff, strong, brittle, and heat-tolerant** like ceramics
- Chemically-, thermally stable, readily machinable, damage tolerant
- Fatigue, creep, and oxidation resistant

MAX/MXenes

The next generation of sustainable, cost-effective materials for technological use



2D materials: unique properties!
Graphene – just Carbon!

"MAX" & "Graphene" = "MXene"

MAX Layered structure \rightarrow Kink and delaminate during deformation \rightarrow 2D early TM carbides/carbonitrides

MXenes: M_2X , M_3X_2 , and M_4X_3

- Bare: metallic (similar to multilayer graphene)
- OH or F terminated: semiconductors with small band gap
- Can be intercalated

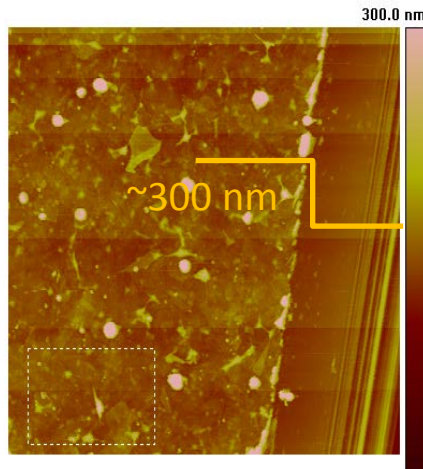
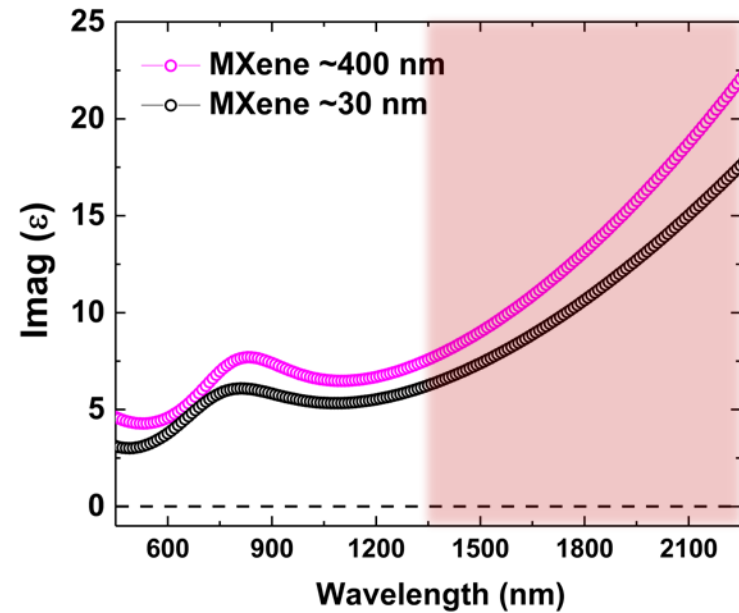
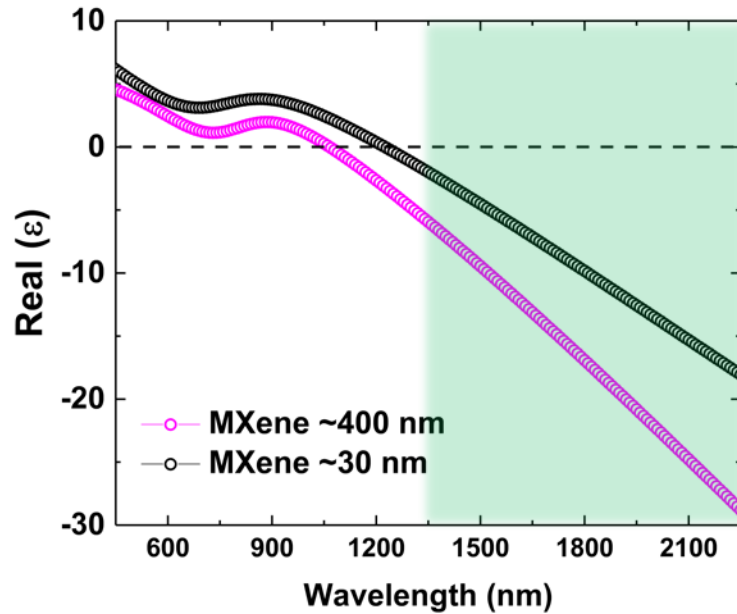
Wiki

M_4X_3

M_3X_2

M_2X

Ti₃C₂T_x MXene thin FILMS



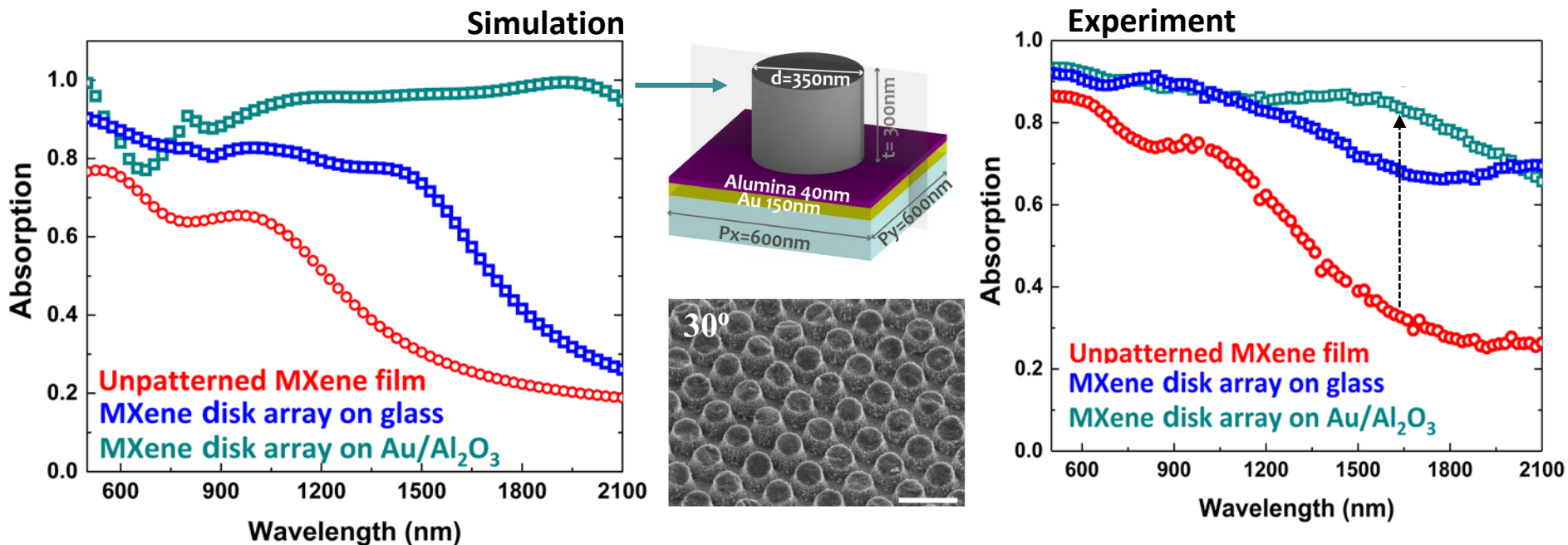
RMS roughness ~ 15 nm

$$\epsilon(\omega) = \epsilon_{\infty} - \frac{\omega_p^2}{\omega(\omega + i\Gamma_p)} + \frac{f_1 \omega_1^2}{\omega_1^2 - \omega^2 - i\omega\Gamma_1} + \frac{f_2 \omega_2^2}{\omega_2^2 - \omega^2 - i\omega\Gamma_2}$$

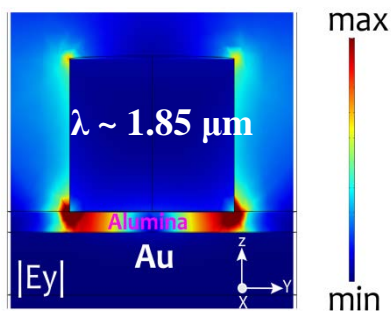
Optical losses

- Inter-band transitions
- Scattering in the rough/disordered structure

MXene BROADBAND ABSORBER



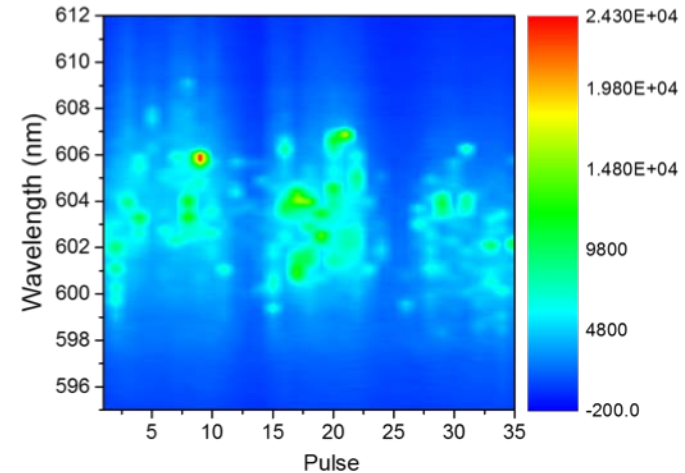
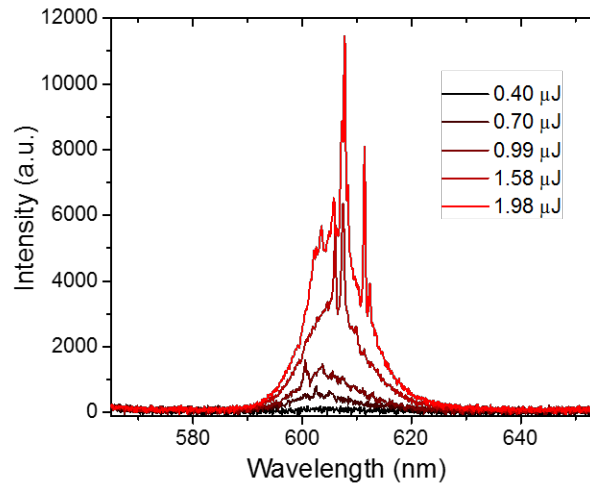
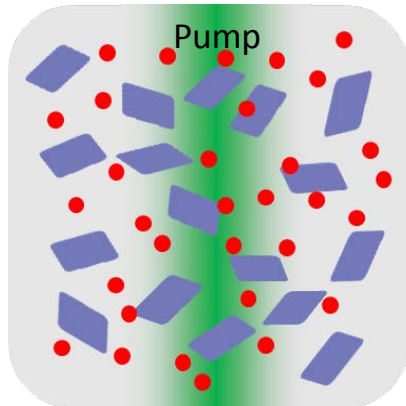
Ti₃C₂ disks/pillar-like structures:
LSPR in NIR



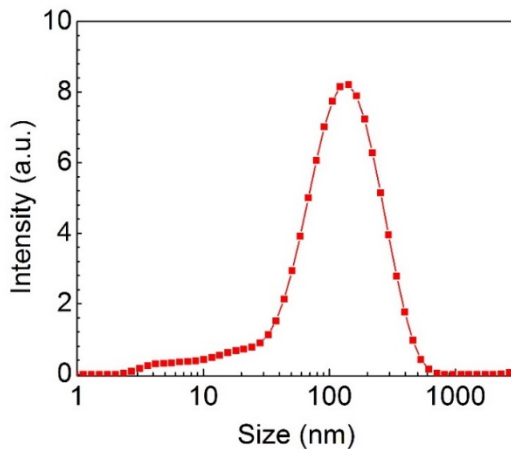
- The first experimental exploration of MXene Ti₃C₂T_x as a functional plasmonic broadband absorber
- **Simple design** of the absorber: utilizes both the inherent absorption in MXene, as well as the scattering enhancement at the plasmonic resonances at longer wavelength
- Optimized to design: **efficiency in NIR >80% in $\lambda \sim 0.5\text{-}1.6\mu\text{m}$**

MXenes FOR RANDOM LASING

 Ti_3C_2 flake  R101 molecule



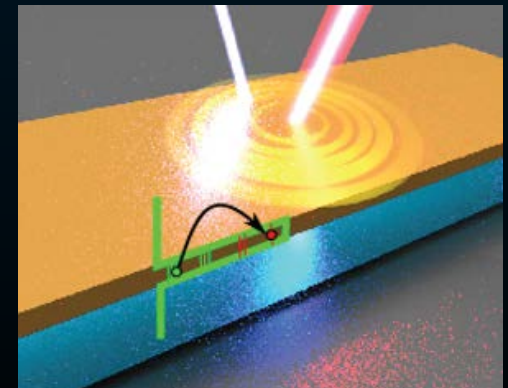
Size distribution of Monolayer $\text{Ti}_3\text{C}_2\text{T}_x$ flakes in water



- Active system composed of 2D graphene nanoflakes can operate as cavity-free random lasers due to the ultra low threshold of saturable absorption of graphene. Phys. Rev. Lett. 116, 217401 (2016)
- Experimentally demonstrated random lasing with $\text{Ti}_3\text{C}_2\text{T}_x$ nanoflakes (diameter ~ 85 nm) and dye molecules
- The lasing effect can be tunable by varying the concentration of $\text{Ti}_3\text{C}_2\text{T}_x$ nanoflakes

OUTLINE

- Plasmonics: Loss and Gain
- Expanding Materials Playground for Plasmonics and Nanophotonics
- Metal Nitrides
- Transparent Conducting Oxides
- Material Requirements: Tunability & T-Stability
- Ultra-Thin Plasmonic Metal Nitrides
- MXenes: Novel Quasi-2D Materials
- Outlook



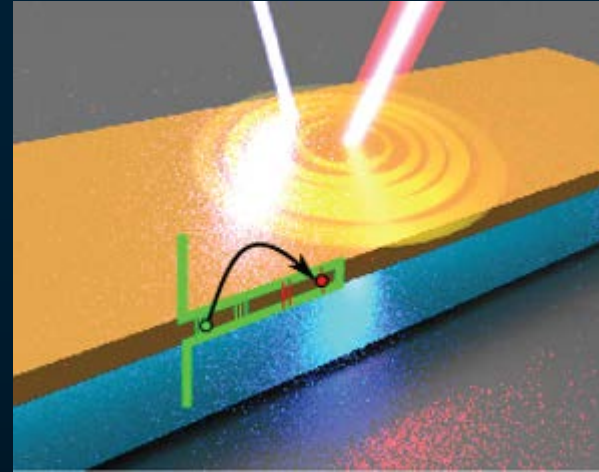
SWITCHABLE/DURABLE/FLEXIBLE PHOTONICS

PLASMONIC CERAMICS

- Durable//high-T/intensity stable/nonlinear
- Ultra-thin/CMOS-compatible

CONDUCTING OXIDES

- Plasmonic materials in NIR
- Great switching opportunities



Ultra-Thin Plasmonic Films

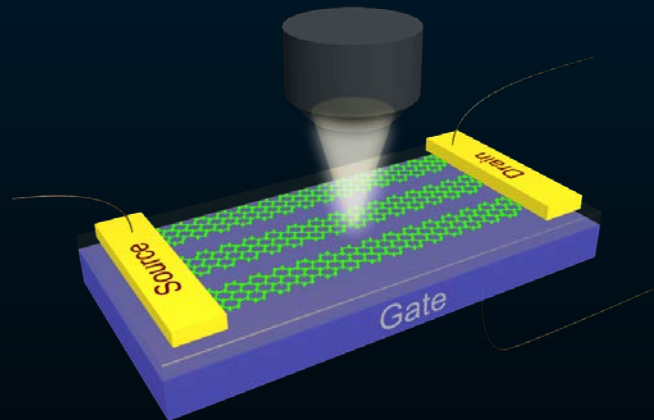
- Quantum confinement enhanced nonlinearities
- Dynamic control over optical response
- Highly confined plasmons

GRAPHENE/2D/MXenes

- Strong electrical tunability/Highly confined SPs

Applications

- Flat Optics, Flexible/Conformal Optics, TPV
- Optical Modulators, NIR/VIS photodetectors, Lasers, THz polarization controllers



TEAM AND SUPPORT



TEAM AND SUPPORT

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